### **Sponsored Research** September 1, 2021



# Sessa Investment Research

## New Growth Phase on Convergence of Drivers

'Fifty Shades of Green' in Power Management ICs and Power Discrete

### **SUMMARY**

- High growth in Torex Semiconductor Group net sales and profits was temporarily interrupted by the significant slowdown in global trade in CY2019 due to escalation of the US-China tariff dispute, followed by initial adverse impact on global economic activities under the pandemic during 1H 2020. The Group reported FY3/20 results of net sales -10.0% and OP -56.3%, followed by 1H 3/21 results of OP down a further -21.0%. However, business conditions improved rapidly from the 2H, and despite weak 1H results, the Group reported full-term FY3/21 net sales +10.3% and OP +78.3%, with the global reset period now squarely in the rear-view mirror.
- The sheer speed of the turnaround can best be illustrated by the exhibit on P3 of new 5-year MTP targets just released in February along with the 3Q upward revision, only to see full-term guidance revised up again in the 4Q, along with significantly higher forecasts for FY3/22. These upward revisions for FY3/21 and FY3/22 overlayed on the initial 5-year MTP targets would imply a decline in FY3/23, which of course the company does not expect. Initial company estimates for FY3/22 are for consolidated net sales +9.6%, OP +65.4% and OPM rising from 5.1%  $\rightarrow$  7.7%. MTP targets include raising OPM to 10.0% in FY3/24 and 11.4% in FY3/26 (year 5).
- Since the company has entered a new phase of accelerated growth, nearly half of this report is devoted to examining the current status and outlooks for three key medium-term growth drivers listed below, along with Torex and Group subsidiary Phenitec product solutions to meet needs arising from these various applications. The new MTP promotes 'GX green transformation' through promoting power-saving circuits, reducing mounting board area and promoting low power-loss devices that suppress heat generation, along with early commercialization of next-generation power devices which will contribute greatly to addressing climate change.



### **Full Report**



#### Focus Points:

Power management IC specialist with attractive growth profile from new applications driven by 5G, IoT-connected devices and the electrification of cars.

	Key Indicator	s
Share	e price (8/31)	2,645
YH (2	1/7/14)	3,330
YL (22	1/1/14)	1,285
10YH	(21/7/14)	3,330
10YL	(14/5/20)	725.8
Shrs o	out. (mn shrs)	11.55
Mkt d	ap (¥ bn)	30.56
EV (¥	bn)	27.23
Shr e	qty ratio (6/30)	64.5%
22,3	P/E (CE)	16.5x
22.3	EV/EBITDA (CE)	6.5x
21.3	ROE (act)	4.9%
21.3	P/B (act)	1.45x
22.3	DY (CE)	1.51%

#### 6M weekly share price



Source: SPEEDA

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This report was prepared by Sessa Partners on behalf of TOREX SEMICONDUCTOR, LTD, Please refer to the legal disclaimer at the end for details.





### **TOREX SEMICONDUCTOR Consolidated Financial Highlights**

[I-GAAP]	FY3/17*	FY3/18	YoY	FY3/19	YoY	FY3/20	YoY	FY3/21	YoY	FY3/22	YoY	FY3/22	YoY
JPY mn. %	act	act	pct	act	pct	act	pct	act	pct	init CE	pct	rev'd CE	pct
Net sales	21.560	23,997	11.3	23.897	(0.4)	21.501	(10.0)	23.713	10.3	26.000	9.6	28,500	20.2
Gross profit	5 900	7 177	21.6	6 4 9 4	(9.5)	5 452	(16.0)	5 959	93		5.0		
GPM	27.4%	29.9%		27.2%	(510)	25.4%	(2010)	25.1%	5.5				
SG&A expenses	4 649	4 964	68	4 943	(0 4)	4 774	(3.4)	4 750	(0.5)	_		_	
ratio to sales	21.6%	-,504 20 7%	0.0	20.7%	(0.4)	27.2%	(3.4)	20.0%	(0.5)				
FRITDA	2 470	20.770	27 /	20.770	(16.2)	1 990	(24.5)	20.070	21 5	3 5/19	16.8	1 169	72 /
ratio to sales	2, <del>4</del> 70 11 5%	12 1%	27.4	11 0%	(10.2)	9.3%	(24.3)	10.2%	21.5	12 7%	40.0	11.6%	72.4
Operating profit	1 251	2 212	76.8	1 551	(29.9)	678	(56.3)	1 209	78.3	2 000	65.4	2 500	106 7
	5.8%	0.2%	70.0	6.5%	(23.3)	3.7%	(30.3)	5 1%	70.5	7 7%	05.4	2,500	100.7
Non operating income	5.0%	101		212		J.270 70		J.170				0.070	
	- 05	101		217				- 55		_		_	
Non operating expenses	111	215		12		01		00					
	414	212		45		20		90					
Porez iosses	334	1 000	120 6	1 0 2 0	(0.0)	58	(62.0)	40	70 4	2 000	65.0	2 500	107.2
ordinary profit	900	1,998	120.6	7.00	(8.9)	2.10	(02.9)	<b>1,200</b>	78.4	2,000	05.8	2,500	107.5
	4.2%	8.5%		7.0%		3.1%		5.1%		1.1%		8.8%	
Extraordinary income	2,561	34		8		32		27		_		_	
Extraordinary losses	31	62		23		117		62		_		_	
Profit before income taxes	3,435	1,971		1,805		592		1,1/1		_		_	
lotal income taxes	331	561		484		1/4		238		_		_	
Profit	3,105	1,410		1,321		417	(	934		_			
Profit ATOP	2,931	902	(69.2)	1,049	16.3	418	(60.2)	934	123.6	1,400	50.0	1,750	87.4
ratio to sales	13.6%	3.8%		4.4%		1.9%	( <b>)</b>	3.9%		5.4%		6.1%	
Cash and deposits	7,769	10,835	39.5	10,982	1.4	9,281	(15.5)	11,737	26.5	_			
ST loans payable	2,423	2,483		1,903		2,902		2,902		—		_	
Current portion of LP	1,174	1,103		1,021		605		1,030		—		_	
Current and LT lease oblig.	129	80		45		99		93		_		_	
LT loans payable	2,496	1,394		1,748		1,143		3,363		-		-	
Total interest-bearing debt	6,223	5,059	(18.7)	4,716	(6.8)	4,749	0.7	7,387	55.6	—		-	
Net IBD (net cash)	(1,547)	(5,776)	273.4	(6,266)	8.5	(4,533)	(27.7)	(4,350)	(4.0)	—		—	
Total shareholders' equity	11,172	14,429	29.2	19,671	36.3	19,053	(3.1)	19,634	3.0	_		_	
Treasury shares	(829)	(416)		(206)		(788)		(750)		—		—	
Accumul. other comp. inc.	260	75		(77)		(381)		156		_		_	
Foreign currency transl.	93	26		(64)		(251)		189		_		_	
adj.				(		()							
Non-controlling interests	4,165	4,582		44		-		-		-		-	
Total net assets	15,598	19,085	22.4	19,638	2.9	18,672	(4.9)	19,790	6.0	—			
Total liab. and net assets	25,210	27,995	11.0	28,386	1.4	27,847	(1.9)	31,512	13.2	—			
Equity Ratio (%)	45.3%	51.8%		69.0%		67.1%		62.8%		—		—	
ROE (%)	26.3%	7.0%		6.2%		2.2%		4.9%		—		—	
DOE (%)	2.7%	2.6%		2.5%		2.3%		2.0%		_		_	
Capex	925	1,150	24.4	3,324	188.9	1,497	(55.0)	1,179	(21.2)	2,019	71.2	2,630	123.1
Depreciation	1,219	934	(23.4)	1,085	16.2	1,312	20.9	1,208	(7.9)	1,549	28.2	1,669	38.1
R&D expense	229	405	76.9	357	(11.9)	403	12.9	457	13.4	504	10.3	—	
Total dividends paid	305	341	11.8	425	24.6	438	3.1	396	(9.6)	—		—	
CF from operating activities	1,635	2,335	42.8	2,700	15.6	1,145	(57.6)	1,790	56.4	—			
CF from investing activities	2,715	(697)		(3,257)		(1,550)		(1,546)		—		—	
Free cash flow (FCF)	4,350	1,638		(557)		(405)		245		—		—	
CF from financing activities	(994)	1,152		(928)		(1,177)		2,175		—		—	
Shares issued and out. (000)	9,539.2	11,089.2		11,554.2		11,554.2		11,554.2		_		_	
Treasury shares (000)	520.8	255.6		148.2		649.6		614.3		_		_	
EPS (¥)	308.77	99.44		95.89		38.03		85.42		127.97		159.96	
DPS (¥)	32.00	34.00		38.00		40.00		36.00		40.00		40.00	
BPS (¥)	1,267.65	1,338.74		1,717.90		1,712.30		1,808.96		_		_	
Yen-dollar rate (USD)	108.9	110.8		110.7		109.1		106.2		109.0		109.0	
Overseas sales ratio**	71.9%	71.0%		71.8%		67.2%		70.5%		_		_	

\*Note: the Company announced on March 14, 2016 that the Board of Directors had resolved to make PHENITEC SEMICONDUCTOR a consolidated

subsidiary by underwriting a PHENITEC capital increase through third-party placement, and it completed the transaction on April 1, 2016. Source: compiled by Sessa Partners from YUHO financial statements and IR results briefing materials. \*\*FC-denominated sales.



JPY mn





New 5-Year MTP 2021 – 2025 [FY3/22 – FY3/26]

The new MTP promotes **'GX** green transformation' through promoting power-saving circuits, reducing mounting board area and promoting low power-loss devices that suppress heat generation.

Parent Torex will continue to focus on developing high value-added power management ICs, including further share expansion of inductor built-in micro DC/DC converters, products specialized for 5G/IoT, solutions for solid-state and semi solid-state batteries, ultra-compact large-capacity packages, etc.

Initiatives for Phenitec include development of silicon-based power devices and compound semiconductors at Kagoshima, and working on completion of the Daiichi Plant integration project at Okayama.

Initially announced targets had implied 5Y CAGR of sales +8.3% and OP +34.8%, and recalculated to reflect FY3/21 actual results are sales +8.0% and OP +27.0%.



### TOREX Group Net Sales, OP and OPM New MTP 2021 – 2025 Targets (JPY mn)







From a company contributing to society with compact, power-saving technologies

Source: compiled by Sessa Partners from New MTP briefing materials published February 15, 2021. \*Note: announced targets only reflect revised estimates as of 3Q FY3/21 results.







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### Powerfully small.





"Micro DC/DC" XCL Series Ultra small DC/DC converters that integrate a coil and a control IC. Simultaneously achieve space-saving, high efficiency, low noise, high heat dissipation, and low cost.

# Life is analog.

Torex power management ICs: Supporting electronic devices in every field



Source: company website





### **PART ONE:**

Introduction to Analog ICs and Power Mgt ICs



### Introduction: 'Life is analog.'

The TOREX SEMICONDUCTOR Group is engaged in the design, manufacture and sale of analog ICs and discrete semiconductors employing CMOS process, specializing in power management ICs, including voltage regulators and step-up and step-down DC/DC converters. Analog ICs account for roughly 13% of the \$500bn+ global market for semiconductors, and power management ICs (or PMICs) are a key subset of analog. Electrical devices often have multiple internal voltages (5V, 3.3V, 1.8V etc.) and multiple sources of external power (wall outlet, battery). PMICs are required in all microcontroller modules for embedded applications, which contain one or more CPUs, memory and programmable input/output peripherals. PMICs perform functions such

### WSTS Worldwide Semiconductor Billings by Product (\$ mn, LHS): 21Y CAGR = 7.0%



Source: compiled by Sessa Partners from World Semiconductor Trade Statistics (WSTS) data. 21Y CAGR from CY2001.

### WSTS YoY Trend for Analog ICs (\$ mn, LHS): 21Y CAGR = 5.5%



Source: compiled by Sessa Partners from World Semiconductor Trade Statistics (WSTS) data.

Relative to highly volatile memory ICs for example, analog ICs have demonstrated stable growth over the medium-term, which is attributed to demand more in line with the macroeconomy, as they are used in applications in virtually every field.

Power management ICs are a key subset of analog ICs, and PMICs are required in all microcontroller modules (MCUs), performing functions such as voltage regulation, undervoltage protection and voltage conversion.





#### WSTS Worldwide Semiconductor Billings by Product

USD mn, %	CY1999	CY2000	CY2001	CY2002	CY2003	CY2004	CY2005	CY2006	CY2007	CY2008	CY2009	CY2010	CY2011
WW Semiconductors	149,379	204,394	138,963	140,713	166,426	213,027	227,484	247,716	255,645	248,603	226,313	298,315	299,521
Discrete	13,070	16,923	12,185	12,345	13,347	15,762	15,244	16,587	16,809	16,935	14,175	19,802	21,387
<ul> <li>Optoelectronics</li> </ul>	5,778	9,805	7,372	6,790	9,545	13,726	14,902	16,280	15,901	17,902	17,043	21,702	23,092
Sensors	313	721	913	1,056	3,569	4,767	4,541	5,339	5,126	5,111	4,753	6,903	7,970
<ul> <li>Analog ICs</li> </ul>	22,082	30,516	23,180	23,913	26,794	31,367	31,922	36,940	36,453	35,637	32,001	42,285	42,338
Micro ICs	41,275	50,322	37,270	38,067	43,526	50,734	54,687	53,939	56,211	53,140	48,330	60,633	65,204
<ul> <li>Logic ICs</li> </ul>	34,575	46,880	33,166	31,502	37,139	49,535	57,670	60,158	67,292	73,531	65,215	77,377	78,782
<ul> <li>Memory ICs</li> </ul>	32,286	49,227	24,875	27,041	32,506	47,136	48,519	58,473	57,854	46,348	44,797	69,614	60,749
Product Breakdown													
WW Semiconductors	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0
<ul> <li>Discrete</li> </ul>	8.7	8.3	8.8	8.8	8.0	7.4	6.7	6.7	6.6	6.8	6.3	6.6	7.1
<ul> <li>Optoelectronics</li> </ul>	3.9	4.8	5.3	4.8	5.7	6.4	6.6	6.6	6.2	7.2	7.5	7.3	7.7
Sensors	0.2	0.4	0.7	0.8	2.1	2.2	2.0	2.2	2.0	2.1	2.1	2.3	2.7
<ul> <li>Analog ICs</li> </ul>	14.8	14.9	16.7	17.0	16.1	14.7	14.0	14.9	14.3	14.3	14.1	14.2	14.1
Micro ICs	27.6	24.6	26.8	27.1	26.2	23.8	24.0	21.8	22.0	21.4	21.4	20.3	21.8
<ul> <li>Logic ICs</li> </ul>	23.1	22.9	23.9	22.4	22.3	23.3	25.4	24.3	26.3	29.6	28.8	25.9	26.3
Memory ICs	21.6	24.1	17.9	19.2	19.5	22.1	21.3	23.6	22.6	18.6	19.8	23.3	20.3
YoY Trend													
WW Semiconductors	-	36.8	(32.0)	1.3	18.3	28.0	6.8	8.9	3.2	(2.8)	(9.0)	31.8	0.4
Discrete	-	29.5	(28.0)	1.3	8.1	18.1	(3.3)	8.8	1.3	0.7	(16.3)	39.7	8.0
<ul> <li>Optoelectronics</li> </ul>	-	69.7	(24.8)	(7.9)	40.6	43.8	8.6	9.2	(2.3)	12.6	(4.8)	27.3	6.4
Sensors	-	130.4	26.6	15.7	238.0	33.6	(4.7)	17.6	(4.0)	(0.3)	(7.0)	45.2	15.5
<ul> <li>Analog ICs</li> </ul>	-	38.2	(24.0)	3.2	12.0	17.1	1.8	15.7	(1.3)	(2.2)	(10.2)	32.1	0.1
Micro ICs	-	21.9	(25.9)	2.1	14.3	16.6	7.8	(1.4)	4.2	(5.5)	(9.1)	25.5	7.5
<ul> <li>Logic ICs</li> </ul>	-	35.6	(29.3)	(5.0)	17.9	33.4	16.4	4.3	11.9	9.3	(11.3)	18.6	1.8
Memory ICs	-	52.5	(49.5)	8.7	20.2	45.0	2.9	20.5	(1.1)	(19.9)	(3.3)	55.4	(12.7)

USD mn, %	CY2012	CY2013	CY2014	CY2015	CY2016	CY2017	CY2018	CY2019	CY2020	CY2021e	CY2022e	3Y CAGR 2	1Y CAGR
WW Semiconductors	291,562	305,584	335,843	335,168	338,931	412,221	468,778	412,307	440,389	527,223	573,440		
Discrete	19,138	18,201	20,170	18,612	19,418	21,651	24,102	23,881	23,804	28,154	29,226		
<ul> <li>Optoelectronics</li> </ul>	26,175	27,571	29,868	33,256	31,994	34,813	38,032	41,561	40,397	44,376	46,684		
Sensors	8,009	8,036	8,502	8,816	10,821	12,571	13,356	13,511	14,962	18,321	19,309		
<ul> <li>Analog ICs</li> </ul>	39,303	40,117	44,365	45,228	47,848	53,070	58,785	53,939	55,658	67,716	71,175		
Micro ICs	60,238	58,688	62,072	61,298	60,585	63,934	67,233	66,440	69,678	75,297	78,160		
<ul> <li>Logic ICs</li> </ul>	81,703	85,928	91,633	90,753	91,498	102,209	109,303	106,535	118,408	138,578	147,175		
Memory ICs	56,995	67,043	79,232	77,205	76,767	123,974	157,967	106,440	117,482	154,782	181,710		
Product Breakdown													
WW Semiconductors	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0	100.0		
Discrete	6.6	6.0	6.0	5.6	5.7	5.3	5.1	5.8	5.4	5.3	5.1		
<ul> <li>Optoelectronics</li> </ul>	9.0	9.0	8.9	9.9	9.4	8.4	8.1	10.1	9.2	8.4	8.1		
Sensors	2.7	2.6	2.5	2.6	3.2	3.0	2.8	3.3	3.4	3.5	3.4		
<ul> <li>Analog ICs</li> </ul>	13.5	13.1	13.2	13.5	14.1	12.9	12.5	13.1	12.6	12.8	12.4		
Micro ICs	20.7	19.2	18.5	18.3	17.9	15.5	14.3	16.1	15.8	14.3	13.6		
<ul> <li>Logic ICs</li> </ul>	28.0	28.1	27.3	27.1	27.0	24.8	23.3	25.8	26.9	26.3	25.7		
Memory ICs	19.5	21.9	23.6	23.0	22.6	30.1	33.7	25.8	26.7	29.4	31.7		
YoY Trend													
WW Semiconductors	(2.7)	4.8	9.9	(0.2)	1.1	21.6	13.7	(12.0)	6.8	19.7	8.8	11.6	7.0
Discrete	(10.5)	(4.9)	10.8	(7.7)	4.3	11.5	11.3	(0.9)	(0.3)	18.3	3.8	7.0	4.3
<ul> <li>Optoelectronics</li> </ul>	13.4	5.3	8.3	11.3	(3.8)	8.8	9.2	9.3	(2.8)	9.8	5.2	4.0	9.2
Sensors	0.5	0.3	5.8	3.7	22.7	16.2	6.2	1.2	10.7	22.5	5.4	12.6	15.6
<ul> <li>Analog ICs</li> </ul>	(7.2)	2.1	10.6	1.9	5.8	10.9	10.8	(8.2)	3.2	21.7	5.1	9.7	5.5
Micro ICs	(7.6)	(2.6)	5.8	(1.2)	(1.2)	5.5	5.2	(1.2)	4.9	8.1	3.8	5.6	3.6
Logic ICs	3.7	5.2	6.6	(1.0)	0.8	11.7	6.9	(2.5)	11.1	17.0	6.2	11.4	7.4
<ul> <li>Memory ICs</li> </ul>	(6.2)	17.6	18.2	(2.6)	(0.6)	61.5	27.4	(32.6)	10.4	31.7	17.4	19.5	9.9

Source: compiled by Sessa Partners from World Semiconductor Trade Statistics (WSTS) data.

Updated to include WSTS Semiconductor Market Forecast Spring 2021 announced June 8, 2021.

as a **voltage regulator** making output voltage less variable than input voltage (e.g. from an input of 5V  $\pm$  50%  $\rightarrow$  to a logic board of 5V  $\pm$  2%), and a **DC/DC converter** dynamically scaling input of direct current from one voltage level to another output voltage. A step-down or buck converter lowers the output voltage, while a step-up or boost converter raises output voltage.



Analog vs. digital

First, it is important to understand the difference between analog and digital, and between discrete and integrated circuits. The word 'analog' can often have a slightly negative connotation as old technology, such as audio recordings on vinyl records or magnetic cassette tapes versus digital optical disks. However, the difference between analog and digital semiconductors is inputs and outputs. Analog semiconductors are designed to accept and process analog signals of real-world phenomena such as light, temperature, humidity, sound, speed, force/touch and **electrical current**. Common functions are amplifiers and filters, such as taking an analog input of sound and making an output of louder sound. They are also referred to as linear ICs because inputs and outputs take on a continuous range of values, and outputs are generally proportional to inputs.

In comparison, digital ICs only accept signals which are binary logic states, such as high or low, true or false etc., which correspond to digital 1s and 0s. Digital signals are only ON (high logic level voltage like 3.3V) or OFF (low logic level voltage like 0V/ground). Analog signals can be a voltage in-between on and off like 1.8V. Analog signals are also continuous values which means they can be an infinite range. Analog ICs are indispensable for interacting with many types of sensors and other devices taking real-world analog signal inputs.

Discrete vs. integrated circuits (ICs) Second is the difference between discrete and integrated circuits. Before the invention of integrated circuits (ICs), all the individual transistors, diodes, resistors, capacitors, and inductors were discrete in nature. Any circuit or a system can produce a desired output based on input. A discrete circuit is constructed of discrete components which are manufactured separately for a single function. The transistor is one of the primary components used in discrete circuits.

An integrated circuit is a microscopic array of electronic circuits (transistors, diodes etc.) and electronic components (resistors, capacitors etc.) that are diffused or implanted onto the surface of semiconductor material such as a silicon wafer. A microcontroller (MCU) is an advanced integrated circuit that is incorporated with additional peripherals. A microcontroller unit can be treated as a small computer on a single integrated circuit that consists of a small central processing unit, crystal oscillator, timers, watchdog and analog I/O. Microcontrollers are designed for embedded applications, in contrast to the microprocessors used in PCs or other general-purpose applications. The majority of MCUs in use today are embedded in industrial equipment, automobiles, appliances and PC peripherals. All microcontroller modules require PMICs.



Source: Elprocus. Key elements of MCUs include: core CPU, program and data memory, input output (I/O) ports, bus connectors, serial interface (communication), clock & timers, ADC/DAC, power management, interrupts.

### Microcontroller (MCU) module example diagram



CY2018 (1) Texas Instruments

(3) Infineon

(5) ST

(6) NXP

(7) Maxim

(8) ON Semi\*

(9) Microchip\*

(10) Renesas\*

(2) Analog Devices\*

(4) Skyworks Solutions

Supple	rs (USI	D mn, % share)					
\$ mn	shr	CY2019	\$ mn	shr	CY2020	\$ mn	shr
10,801	18%	1 Texas Instruments	10,223	19%	1 Texas Instruments	10,886	19%
5,505	9%	2 Analog Devices	5,169	10%	<ol> <li>Analog Devices</li> </ol>	5,132	9%
3,810	6%	(3) Infineon	3,755	7%	(3) Skyworks Solutions	3,970	7%

6%

6%

5%

4%

4%

3%

2%

3,283

3,205

2,564

1,850

1,740

1,532

860

(4) Infineon

NXP

Maxim

ON Semi

Renesas

Microchip

(5) ST

(6)

(7)

(8)

(9)

(10)

Sessa Investment Research

3,820

3,259

2,466

2,000

1,606

1,420

890

7%

6%

4%

4%

3%

2%

2%

### Leading Global Analog IC Su

3,686

3,208

2,645

2,125

1,990

1,389

900

Renesas Source: IC Insights annual press releases, company reports. \*Note: names marked with an asterisk include sales from acquisitions.

Microchip

(5) Skyworks Solutions

(4) ST

(6) NXP

(9)

(10)

(7) Maxim

(8) ON Semi

6%

5%

4%

4%

3%

2%

1%

### indexPro Monthly Click Share Ranking for Boost Converter IC & Buck-Boost Converter IC 🦰

			-					
	March 2021			April 2021			May 2021	
1	Texas Instruments (TI)	10.2%	1	Texas Instruments (TI)	13.3%	1	Texas Instruments (TI)	15.5%
2	<b>Ricoh Electronic Devices</b>	7.0%	2	<b>Ricoh Electronic Devices</b>	7.8%	2	ROHM	9.2%
3	ROHM	5.9%	3	Torex Semiconductor	6.7%	3	Torex Semiconductor	8.9%
4	Torex Semiconductor	5.8%	4	Maxim Integrated	6.6%	4	<b>Ricoh Electronic Devices</b>	7.1%
(5)	New Japan Radio	4.8%	(5)	New Japan Radio	5.9%	(5)	New Japan Radio	6.5%
6	Analog Devices	4.5%	6	Analog Devices	5.6%	6	Analog Devices	6.5%
$\overline{\mathcal{O}}$	ABLIC	4.3%	$\overline{\mathcal{O}}$	ROHM	5.3%	$\overline{\mathcal{O}}$	Maxim Integrated	4.5%
8	Maxim Integrated	4.2%	8	ON Semiconductor	4.4%	8	ON Semiconductor	4.5%
9	ON Semiconductor	4.2%	9	Asahi Kasei Microdevices	3.7%	9	Infineon Technologies	4.0%
(10)	Infineon Technologies	3.7%	(10)	ABLIC	3.6%	(10)	ABLIC	3.9%

Source: monthly click share rankings by indexPro under Electronic Components: Analog & Mixed Signal

In CY2020, the top 10 global suppliers of analog ICs accounted for 63% of the total market, with Texas Instruments accounting for nearly 20% (see upper table above). Sadly, short of paying thousands of dollars for specialized market research, there is no readily available data for analog subset power management ICs. However, indexPro is Japan's largest portal for trade information on electronic and industrial components, targeting designers, developers and production engineers, collating product information of roughly 5,000 manufacturers and 4,000 sales agents/distributors, with over 10,000 users per day (with sister sites in Europe and China).

The monthly click-share rankings above shed some insight into the Company's direct competitors. Out of 46 manufacturers in the category of 'Boost Converter IC & Buck-Boost Converter IC (DC/DC converters)', Torex Semiconductor consistently places no.4 or no.3, which is up one notch from our initiation report in Mar-2020. While this ranking includes many of the global top 10 analog IC suppliers in the upper table, after global no.1 TI, the top 5 consists of Ricoh Electronic Devices, Torex, ROHM and New Japan Radio. ROHM is both a competitor and client of Group subsidiary Phenitec. Since Ricoh Electronic Devices, New Japan Radio, ABLIC and Asahi Kasei Microdevices are unlisted, reported trends at global no.1 TI can offer some insight on industry conditions.

Global no.1 TI as a bellwether for the state of general conditions in the global PMIC market







- INDUSTRIAL
- AUTOMOTIVE
- CONSUMER ELECTRONICS
- COMMUNICATIONS (ICT)

INDUSTRIAL and AUTOMOTIVE are growth applications, while the weights of CONSUMER ELECTRONICS and COMMUNICATIONS (ICT) have been gradually shrinking.

The US-China Trade War put pressure on INDUSTRIAL in 2019, followed by severe pressure on AUTOMOTIVE in 2020 due to production cuts as a result of the pandemic, coinciding with a rebound in CONSUMER ELECTRONICS due to special demand from the shift to working at home.

### $\star$ Applications are key to understanding and monitoring demand trends

The 4 main applications shown on the left comprise a standard classification system for the global electronic components supply chain overall, not just analog ICs and power management ICs. It is an intelligent and efficient way to organize the vast billions of electronic components by end market applications as part of understanding and monitoring demand trends for final products. In FY12/20, global no.1 analog IC supplier Texas Instruments with a 20% global share had Analog segment revenue of \$10,886mn, and total revenue of \$14,461mn. In FY3/21, Torex Semiconductor had consolidated revenue of ¥23,712mn (\$224mn @USD 106). Is it valid to compare a specialist niche player like Torex to the global no.1 supplier TI, which is 65x larger in scale?

The answer is yes, because semiconductors are a global industry, subject to the same demand trends across the global market. The graph below shows the trend of revenue breakdown for TI by applications. The 4 main applications shown to the left accounted for 92% in 2020. The key takeaway from this graph is that out of the 4, the weights of industrial and automotive are rising, while the weights of personal electronics and that



### **Texas Instruments End Market (Application) Revenue Mix**

**Torex Semiconductor Parent End Market (Application) Revenue Mix** 







### Texas Instruments Power Management: Applications by Market Segment and Sector

AUTOMOTIVE	INDUSTRIAL	INDUSTRIAL (continued)
Advanced Driver Assistance Systems (ADAS)	Appliances	• Display
Camera - front camera	Appliance battery chargers	Digital signage
Radar - front long-range radar	Appliance battery packs	Lighting: LCD backlight
Camera - rear camera	Cooker hoods	Lighting: signage
Camera - multi-camera system w/central processing	Cordless handheld garden tools	Electronic Point of Sale
Ultrasound -ultrasound park assist	Dish washers	ATMS (automated teller machines)
<ul> <li>Body Electronics and Lighting</li> </ul>	Mains powered tools	Barcode scanner
Body control module and gateway - BCM	Refrigerators and freezers	Currency counter
Small motors - door	Vacuum cleaners	Electronic shelf label
Automotive lighting - exterior lighting - headlight	Vacuum robots	EPOS, ECR and cash drawer
Automotive lighting - exterior lighting - rear light	Washers and dryers	Portable data terminal
Heating and cooling - HVAC blower and damper	<ul> <li>Building automation</li> </ul>	<ul> <li>Factory Automation and Control</li> </ul>
Automotive lighting - interior lighting	Air quality and gas detection	Analog input module
Security systems - passive entry passive start (PEPS Fob)	Analog security camera	Analog output module
Mirrors - side	Daylight harvester	Barcode readers
<ul> <li>Hybrid, Electric and Power Train Systems</li> </ul>	Digital alarm communicator	Camera
Engine management - actuators - engine fan	Door and window sensor	Communications module
Engine management - actuators - pump	Door keypads and readers	CPU (PLC controller)
Engine management - actuators - E Turbo/charger	Fire alarm control panel (FACP)	Digital input module
Eng mgt - ECU - gasoline and diesel eng platform	Fire safety sounder, speaker, strobe	Digital output module
HEV/EV - battery management system (BMS)	Gas detector	Displacement transmitter (angular, linear, axial)
HEV/EV - DC/DC converter	Glass break detector	Flow transmitter
HEV/EV - inverter and motor control	Home remote control	Industrial monitor
HEV/EV - on-board (OBC) and wireless charger	HVAC motor control	Level transmitter
Powertrain sensors - HEV/EV	HVAC sensor transmitter (4-20ma)	Lighting
Transmission - ECU - automatic	HVAC system controller	Other PLC
<ul> <li>Infotainment and Cluster</li> </ul>	HVAC valve and actuator control	Portable monitor
Cluster - mid-range 4 to 7-inch hybrid	Intrusion control panel	Pressure transmitter
HMI and display - touch display	Intrusion HMI keypad	Process analytics (PH, gas, concent., force, humidity)
Head unit - with integrated display	IP network camera	Single board computer
Head unit - with remote display	Key Fob or panic button	Special function module (encoder etc.)
Heads-up display	Motion detector (PIR, UWAVE etc.)	Temperature transmitter
Media interface - media hub	People counting	Transducer module
Media interface - USB charge	Remote annunciator	• Grid Infrastructure
Telematics - telematics control unit	Smart plug	Distribution automation - fault indicators
	Smoke and heat detector	Distribution automation - secondary power distrib.
	Thermostat	Distribution automation - terminal unit
	Video doorbell	Protection relay - bay control
	Video recorder (NVR, DVR etc.)	Protection relay - distribution feeder protection
	Water leak detector	Protection relay - transmission line protection
	Wireless environmental sensor	Substation automation - transducer

AUTOMOTIVE



INDUSTRIAL





### Texas Instruments Power Management: Applications by Market Segment and Sector (continued)

INDUSTRIAL (continued)	PERSONAL ELECTRONICS	COMMUNICATIONS EQUIPMENT
Medical, Healthcare and Fitness	Mobile Phones	Enterprise Switching
Dialysis machines	Handset: smartphone	Ethernet switch
Fitness machines	Power: battery management	IP phone: wired
Insulin pumps	Wireless chargers	Wireless access point system
Motor Drives	PCs and Notebooks	Telecom Infrastructure
AC inverter and VF drives	Desktop PC	AC/DC power supply: dual analog controller
Active front ends for industrial drives	Embedded PC	AC/DC power supply: dual digital controller
Building and industrial pumps	Mobile internet device	AC/DC power supply: single analog controller
CNC drives	Notebook PC	AC/DC power supply: single digital controller
E-Mobility (E-bike, E-scooter, elec util vehicles)	Power supply: AC/DC, isolated, no PFC, <90W	Optical line card
Industrial stepper drive	<ul> <li>Printers and Other Peripherals</li> </ul>	Optical networking: EPON
Non-military drones	3D printers	Optical networking: video over fiber
Position encoders and resolvers	Digital picture frame (DPF)	Power over ethernet (PoE)
Servo drives and motion control	Mouse	Power: telecomm DC/DC module: analog
Other Industrial	Network projector front end	Power: telecomm DC/DC module: digital
Down hole drilling	Power bank solutions	Telecom base band unit
Power Delivery	Printer	Telecom shelter: filter unit
Industrial AC-DC	Scanner	Telecom shelter: power distribution unit (PDU)
Medical PSU	Speaker: USB	Telecom shelter: wireless battery monitoring
Merchant DC-DC	• Storage	Telecom tower: remote electrical tilt unit (RET)
Merchant din rail power supply	Solid state drive (SSD): client	Telecom tower: remote radio unit (RRU)
Merchant telecom rectifiers	• Tablets	Telecom tower: tower mounted amplifier (TMA)
Power transfer units	Tablet: multimedia	Video broadcasting and infra: scalable platform
Single phase UPS	<ul> <li>TV, Set-Top Box and Audio</li> </ul>	Video bc and infra: IP-based multi-format transcoder
Three phase UPS	Audio dock: basic	Video communications system
<ul> <li>Space, Avionics and Defense</li> </ul>	Audio dock: performance	Video conferencing: IP-based HD
Military and avionics imaging	Audio dock: portable	Wireless Infrastructure
Military munitions and targeting	AV receiver	Backhaul: microwave backhaul
Weather radar	Digital still camera (DSC)	Digital repeater
<ul> <li>Test and Measurement</li> </ul>	Digital video camera (DVC)	Small cells - enterprise FEMTO base station
Oscilloscopes (DSO)	DVD recorder and player	Small cells - micro base station
Scales and weight	Embedded camera system	Software defined radio (SDR)
Semiconductor test equipment	GPS: personal navigation device	Tetra base station
Signal analyzers (vector signal analyzers - VSA)	Internet radio player	
Signal generators (vector signal generators - VSG)	MP3 player/recorder (portable audio)	
Spectroscopy	Portable DVD player	ENTERPRISE SYSTEMS
Spectrum analyzers	Portable media player	• Servers
	STB, DVR and streaming media	Network attached storage
	TV: LCD/digital	Server motherboard
	Wireless headset	Server PSU
	Wearables (Non-Medical)	Solid state drive (SSD): enterprise
	Smart clothing	Video analytics server

#### PERSONAL ELECTRONICS

Smart patches Smart watches





COMMUNICATIONS EQUIPMENT



Smart glasses, ID tags and augmented reality (AR)



### **TOREX** Power Management IC Applications Brief Summary



9



Sales Breakdown by Product/Service: PMICs account for roughly 40%	Ś
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[J-GAAP]	FY3/17	FY3/18	YoY	FY3/19	ΥοΥ	FY3/20	YoY	FY3/21	ΥοΥ
JPY mn, %	act	act	pct	act	pct	act	pct	act	pct
Net sales	21,560	23,997	11.3	23,897	(0.4)	21,501	(10.0)	23,713	10.3
<ul> <li>DC/DC Converters</li> </ul>	2,997	2,889	(3.6)	3,092	7.1	3,162	2.2	3 <i>,</i> 025	(4.3)
<ul> <li>Voltage Regulators</li> </ul>	4,872	5,165	6.0	4,834	(6.4)	4,520	(6.5)	4,503	(0.4)
<ul> <li>Voltage Detectors</li> </ul>	1,565	1,586	1.4	1,672	5.4	1,572	(6.0)	1,640	4.4
Discrete	10,942	14,063	28.5	13,732	(2.4)	11,362	(17.3)	13,825	21.7
• Other	1,183	294	(75.1)	566	92.4	885	56.4	720	(18.7)
Net sales	100.0%	100.0%	—	100.0%	—	100.0%	—	100.0%	—
<ul> <li>DC/DC Converters</li> </ul>	13.9%	12.0%	-	12.9%	—	14.7%	_	12.8%	—
<ul> <li>Voltage Regulators</li> </ul>	22.6%	21.5%	-	20.2%	—	21.0%	_	19.0%	_
<ul> <li>Voltage Detectors</li> </ul>	7.3%	6.6%	-	7.0%	—	7.3%	_	6.9%	_
<ul> <li>Discrete</li> </ul>	50.8%	58.6%	—	57.5%	—	52.8%	—	58.3%	-
• Other	5.5%	1.2%	_	2.4%	_	4.1%	_	3.0%	_

Source: compiled by Sessa Partners from YUHO financial statements

...continued from P8

The EXACT SAME application trends are observed by the global no.1 supplier as well as the small niche player because semiconductors are a global market affected by the same demand factors. of communications equipment are shrinking. The coronavirus pandemic in 2020 had a temporary negative impact on automotive growth, while seeing a special jump in personal electronics from demand due to 'stay at home' changing workstyles, but the aforementioned trends remain intact.

The lower graph on P8 shows the trend of revenue breakdown for parent Torex by applications. As it turns out, the EXACT SAME trends for the 4 main applications can be observed for specialist niche player Torex, only 1.5% the scale of global no.1 TI. This is supplementary information provided voluntarily by the Company, and after acquiring the majority stake in Phenitec, the Company decided from FY3/17 results to provide information concentrating on focus growth applications, so figures for consumer electronics and communications equipment are lumped together under 'Other,' but according to the Company, the trend for both is similar to those reported by TI.

Torex also experienced similar positive and negative impacts in 2020 under the pandemic. Note however that the decline in Torex automotive might appear somewhat exaggerated, but that was due to the previous year getting a special boost from China's initiative to install ETC in highway toll booths and vehicles nationwide, as well as high growth in drive recorders in Japan. This was a prime example of how being a small and nimble niche player helped outperform the underlying market, which was suffering from automotive production cutbacks resulting from the US-China tariff war. Of course, this makes a high base for comparison in the following period, making above average growth difficult to sustain over the medium-term.

The table above is further supplemental disclosure by Torex of the trend in net sales by product/service. However, compared with data on the trend by applications, there is very little utility in the trend of sales for the 3 major types of power management ICs. The key takeaway from this data is simply that PMICs account for roughly 40% of consolidated net sales, versus roughly 60% for discrete by Group subsidiary Phenitec.

Next, we have identified two very useful checkpoints for monitoring general earnings conditions for the industry, as well as the general state of the global electronics supply chain, in the absence of readily available industry data on power management ICs.



#### Texas Instruments Quarterly Earnings Trend since Escalation of the US-China Tariff War

		· 0·										
USD mn, %	Q3 2018	Q4 2018	Q1 2019	Q2 2019	Q3 2019	Q4 2019	Q1 2020	Q2 2020	Q3 2020	Q4 2020	Q1 2021	Q2 2021
Revenue	4,261	3,717	3,594	3,668	3,771	3,350	3,329	3,239	3,817	4,076	4,289	4,580
Analog	2,907	2,638	2,518	2,534	2,674	2,497	2,460	2,434	2,865	3,127	3,280	3,464
<ul> <li>Embedded Processing</li> </ul>	894	791	796	790	724	633	653	546	651	720	767	780
Other	460	288	280	344	373	220	216	259	301	229	242	336
Revenue YoY	3.5	(0.9)	(5.1)	(8.7)	(11.5)	(9.9)	(7.4)	(11.7)	1.2	21.7	28.8	41.4
<ul> <li>Analog YoY</li> </ul>	7.7	4.1	(1.9)	(5.8)	(8.0)	(5.3)	(2.3)	(3.9)	7.1	25.2	33.3	42.3
<ul> <li>Embedded Proc. YoY</li> </ul>	(4.0)	(11.7)	(14.0)	(16.2)	(19.0)	(20.0)	(18.0)	(30.9)	(10.1)	13.7	17.5	42.9
Other YoY	(5.5)	(9.7)	(5.7)	(10.4)	(18.9)	(23.6)	(22.9)	(24.7)	(19.3)	4.1	12.0	29.7
Operating Profit	1,937	1,516	1,379	1,506	1,589	1,249	1,244	1,228	1,609	1,813	1,939	2,213
<ul> <li>Analog</li> </ul>	1,447	1,233	1,088	1,108	1,231	1,050	1,025	1,053	1,320	1,514	1,646	1,778
<ul> <li>Embedded Processing</li> </ul>	309	234	249	265	233	160	182	125	187	249	287	312
Other	181	49	42	133	125	39	37	50	102	50	6	123
OP YoY	8.3	(3.0)	(10.9)	(12.0)	(18.0)	(17.6)	(9.8)	(18.5)	1.3	45.2	55.9	80.2
<ul> <li>Analog YoY</li> </ul>	14.1	3.8	(6.7)	(12.3)	(14.9)	(14.8)	(5.8)	(5.0)	7.2	<u> </u>	60.6	68.9
<ul> <li>Embedded Proc. YoY</li> </ul>	(4.9)	(23.8)	(24.1)	(20.7)	(24.6)	(31.6)	(26.9)	(52.8)	(19.7)	55.6	57.7	149.6
Other YoY	(7.2)	(27.9)	(22.2)	15.7	(30.9)	(20.4)	(11.9)	(62.4)	(18.4)	28.2	(83.8)	146.0
OPM	45.5%	40.8%	38.4%	41.1%	42.1%	37.3%	37.4%	37.9%	42.2%	44.5%	45.2%	48.3%
<ul> <li>Analog</li> </ul>	49.8%	46.7%	43.2%	43.7%	46.0%	42.1%	41.7%	43.3%	46.1%	48.4%	50.2%	51.3%
<ul> <li>Embedded Proc.</li> </ul>	34.6%	29.6%	31.3%	33.5%	32.2%	25.3%	27.9%	22.9%	28.7%	34.6%	37.4%	40.0%
• Other	39.3%	17.0%	15.0%	38.7%	33.5%	17.7%	17.1%	19.3%	33.9%	21.8%	2.5%	36.6%

\*Note: operating profit before restructuring and acquisition charges. Source: compiled by Sessa Partners from TI IR website.

#### Torex Semiconductor Quarterly Earnings Trend since Escalation of the US-China Tariff War

JPY mn, %	2Q 3/19	3Q 3/19	4Q 3/19	1Q 3/20	2Q 3/20	3Q 3/20	4Q 3/20	1Q 3/21	2Q 3/21	3Q 3/21	4Q 3/21	1Q 3/22
Net sales	6,267	6,074	5,353	4,797	5,534	5,599	5,571	5,858	5,551	5,762	6,542	7,013
YoY	2.8	0.6	(13.0)	(22.7)	(11.7)	(7.8)	4.1	22.1	0.3	< 2.9	17.4	19.7
Operating profit	676	312	(112)	79	251	205	143	195	66	433	515	636
YoY	6.3	(43.2)	TR	(88.3)	(62.9)	(34.3)	ТВ	146.8	(73.7)	< 111.2	260.1	226.2
OPM	10.8%	5.1%	-2.1%	1.6%	4.5%	3.7%	2.6%	3.3%	1.2%	7.5%	7.9%	9.1%

Source: compiled by Sessa Partners from SPEEDA earnings database.



TI quarterly results are one highly useful checkpoint to identify <u>potential</u> positive or negative surprises in Torex results.

### **★** Texas Instruments reports quarterly results roughly 3 weeks ahead of Torex

TI reports quarterly earnings results roughly 3 weeks ahead of Torex, making it a useful checkpoint to identify any potential positive or negative surprises for Torex results. The most recent two quarters offer a prime example. The tables above show the trend of quarterly results for Texas Instruments and Torex Semiconductor since escalation of the US-China tariff war in Jul-Sep 2018.

On January 26, 2021, TI reported strong 4Q results with total revenue +22% and OP +45%. Of direct implication for Torex, the YoY trend of Analog revenue by quarter was 2Q -3.9%, 3Q +7.1% and 4Q +25.2%, posting a stronger than expected finish in the 4Q. At 16:30 on February 12, 2021, Torex revised up full term FY3/21 guidance: net sales by ¥500mn (+2.2%), and OP by ¥400mn (+80.0%), clearly a positive surprise. Torex reported 3Q results on February 15, net sales +2.9% YoY and OP +111.2% YoY.

On April 27, 2021, TI reported strong 1Q results, posting record quarterly sales and OP. Of direct implication for Torex, following on from brisk 4Q results, 1Q Analog revenue rose +33%, and OP rose +61% YoY. At 16:30 on May 10, Torex revised up full-term guidance again: net sales by ¥200mn (+0.9%), and OP by ¥300mn (+33.3%), another positive surprise. Torex reported 4Q results on May 17, net sales +17.4% YoY and OP +260.1% YoY. We examine the Company's earnings trend in more detail in PART THREE, but the key takeaway here is that there is some utility in checking TI results to identify potential positive or negative surprises ahead of Torex results.





Japan exports to China as a reliable proxy for the general health of the global electronics supply chain

### ★ Another useful checkpoint is monthly Japan exports to China

This second checkpoint is not based on an empirical academic study, rather, our own observations from poring over multiple sources of macro input variables in search of a factor or factors that would help us monitor the general health of the global electronics supply chain. To be sure, we find monthly statistics published by the Japan Electronics and Information Technology Industries Association (JEITA) on production and shipments for a myriad of electronics products extremely helpful in monitoring the domestic market in Japan. Each country has its own body of industry statistics, but with the exception of World Semiconductor Trade Statistics (WSTS), there is very little easily accessible data on the global market. Ultimately, we observed that trade activity was a reliable indicator of real-time trends in business activity, highlighting regional differences in relative strength and weakness.

The upper graph below shows Japan total exports in June 2021 posted growth of +48.6% YoY, exceeding the level in 2010 in the wake of the recovery after the financial crisis. The lower graph shows exports to its no.1 trading partner China rose +27.7% driven by chipmaking equipment, hybrid vehicles and scrap copper. While growth to its no.2 partner the US was a higher +85.7%, driven by autos and car parts, the US figure is a reactionary rise to the sharp COVID decline, while the China figure reflects full-fledged recovery after the effect of the US-China tariff war in 2019.



Source: compiled by Sessa Partners from MOF Trade Statistics of Japan (monthly press releases).

# MOF Monthly Trade Statistics of Japan: Exports



### Robust Statistical Correlation

parameter	since	since
	2014	2018
correlation coefficient (r)	0.841	0.921
coefficient of determination (r <sup>2</sup> )	0.706	0.848

Note: r measures the strength and direction of the linear relationship between two variables. r<sup>2</sup> measures the goodness of fit of a linear regression model (variance of one variable explained by the other). Of course, correlation does not imply causation.

Source: compiled and calculated by Sessa Partners.

Occasional outsized moves by Torex compared with TI in 2019 and 2020 likely reflect the positive (small and nimble) and negative (less essential) aspects of being an SME. Nevertheless, the robust correlation with Japan exports to China can be seen for both companies.

Risks to this correlation include natural disasters or geopolitical flare-ups which could interrupt normal trade



#### Quarterly YoY Trend of Japan Exports to China and TI Analog Revenue

Source: compiled by Sessa Partners from MOF Trade Statistics of Japan and TI earnings releases.

### Quarterly YoY Trend of Japan Exports to China, TI Analog Revenue and Torex Revenue



Source: compiled by Sessa Partners from MOF Trade Statistics of Japan and TI / Torex earnings releases.

Statistical data shown in the upper left table for r and r<sup>2</sup> confirm there is indeed a robust correlation between TI analog revenue and Japan exports to China. In the absence of an empirical study, our thesis to explain this correlation is based on two observations/assumptions. First, while Japan has ceded dominance in mass market consumer electronics to South Korea and China, Japan is still the global leader in many critical electronic components and functional materials that go into those products. Second, while many 'cutting edge' electronics products are designed overseas, final assembly is done in China. Monthly data enables real time checking.

It is worth noting that since 2010, this relationship broke down only twice: the 3 quarters following the 3.11 Tohoku earthquake/tsunami disaster due to supply chain disruptions caused by power shortages from the entire nuclear grid shutdown, and again in the 2H of 2012 due to trade frictions between Japan and China as a result of the Senkaku Islands (called Diaoyu Islands in the P.R.C.) territorial dispute.







#### **PART TWO:**

Torex Group Overview, History and Business Models

### **Torex Semiconductor Group Overview**

The Torex Group has a unique business model, where the parent Torex has a fabless business model specializing in the design and sales of analog ICs, specifically power management ICs, which are required in all microcontroller units (MCUs)/modules, performing functions such as voltage regulation, undervoltage protection and voltage conversion. Voltage transmitted from dry cell or automotive batteries has subtle fluctuations due to decreases in stored electrical energy and changes in the environment such as temperature and electromagnetic noise. If voltage is left unregulated, it may lead to malfunction of electronic equipment, and therefore power management ICs are indispensable for all types of electronic components and products. The medium-term demand outlook is bright with growth in the number of IoT-connected devices accelerating, 5G infrastructure ramping up globally, diffusion of electric vehicles (EVs) entering a new growth phase, and technology advances in connected cars and ADAS (advanced driver-assistance systems).

Subsidiary Phenitec offers a unique foundry service in Japan using CMOS process technology for discrete and power semiconductors. Its comprehensive front-end wafer processing services include: 1) consignment manufacturing of custom products to customer specifications, 2) production of in-house developed original products, and 3) various partial micromachining of silicon wafers such as laser trimming, test & probe, back surface processing and dicing. By providing foundry solutions to meet customer needs, Phenitec is achieving low-cost, high-quality products. As the table on the next page shows, Phenitec was founded in October 1968 as Shinko Electric Co., Ltd., celebrating its 50<sup>TH</sup> anniversary in October 2018. It began manufacturing discrete devices in the late 1970s and early 1980s, with a commitment to Total Productive Maintenance (TPM) activities and emphasis on continually raising quality standards.

### **Torex Semiconductor Group Business Models**







### PHENITEC SEMICONDUCTOR Corp. Corporate History

Date	Event / Milestone		
1968/10	Shinko Electric Co., Ltd. established in Ibara, Okayama Pref.		
1976/3	Diode device manufacturing commenced		
1983/12	Zener diode device manufacturing commenced		
1984/9	Transistor device manufacturing commenced		
1988/5	Total Productive Maintenance (TPM) activities commenced		
1989/5	EPI (epitaxial wafer) Plant completed		
1990/8	Daiichi (No.1) Plant Fab-1 completed, power MOS, CMOS production commenced		
1990/9	Received the PM Business Excellence award		
1990/10	Bipolar IC manufacturing commenced		
1997/8	Obtained ISO 9002 certification, JQA-1829		
1998/10	Company name changed to Phenitec Semiconductor co., Ltd.		
1998/11	QS 9000: obtained 1998 certification		
1999/10	Obtained VDA6 certification (German version of QS 9000)		
1999/12	Daiichi (No.1) Plant Fab-2 completed		
2001/8	Mass production commenced on 6-inch line		
2002/4	Obtained ISO 14001 certification		
2002/8	Kyoto Design Center established		
2003/11	Upgrade to ISO 9001 certification		
2003/12	Daiichi (No.1) Plant Fab-3 completed		
2004/5	ISO/TS 16949: obtained 2002 certification		
2015/10	Acquired Kagoshima Plant from Yamaha Corp., commenced production		
2016/4	Concluded a capital alliance with Torex Semiconductor, becoming a subsidiary		
2017/4	ISO 14001: obtained 2015 certification		
2018/4	Increased capital to JPY 1.6 billion, Torex stake raised to 69.1%		
2018/8	Daiichi (No.1) Plant Fab-4 completed		
2018/9	IATF 16949: obtained 2016 certification (Head Office Plant, Daiichi Plant)		
2018/11	ISO 9001: obtained 2015 certification		
2020/3	ISO 45001: obtained 2018 certification		
с рі			

Source: Phenitec website

### **Torex Semiconductor Group Corporate History**

The history of the company began in October 1989 when the former Torex Semiconductor Co., Ltd. was established as a company responsible for sales of the foundry business of Shinko Electric Co., Ltd. (currently PHENITEC SEMICONDUCTOR Corp.). In order to expand the company's business scale, it was necessary to develop core business other than foundry sales, so the company focused on the field of analog power supply ICs, an under-covered area by major semiconductor manufacturers. The decision to focus on analog power management ICs was due to expectations that the development of final applications that run on batteries would accelerate in the future, and for such products, multiple analog power management ICs would be required to control battery power management.

In 1992 the company launched the XC61AN series voltage detector offering extremely precise detection and low power consumption. The XC61AN series was introduced for use on a portable cassette player with nickel-hydrogen rechargeable batteries. At the time, the ability to accurately detect the minimum 0.8V needed to run the player was a highly requested feature, and meeting this requirement made much longer play time possible.



October 2018 50<sup>™</sup> Anniversary









### **TOREX SEMICONDUCTOR LTD. Corporate History**

Date	Event / Milestone			
1005/2	Established as a subsidiary of Shinko Electric Co., Ltd. (currently PHENITEC SEMICONDUCTOR			
1995/3	Corp.) in Ibara, Okayama Pref.			
	Established head office in Echujima, Koto-ku, Tokyo			
1996/11	Established TOREX SEMICONDUCTOR (S) PTE LTD in Singapore (81%) as the first overseas base			
1997/3	Established Torex Device Co., Ltd.			
2000/6	Established TOREX SEMICONDUCTOR DEVICE (HONG KONG) LTD (currently ISM ASIA LIMITED)			
2000/9	Established TOREX USA Corp.			
2001/3	Established TOREX SEMICONDUCTOR EUROPE LIMITED			
2002/5	Made TOREX SEMICONDUCTOR (S) PTE LTD a wholly owned subsidiary			
2002/8	Head office moved to Nihonbashi Kayabacho, Chuo-ku, Tokyo			
2002/10	Established Kansai branch office in Ibaraki, Osaka			
2003/3	Obtained ISO 14001 certification (head office)			
2003/5	Established Shanghai office			
2004/4	Opened Sapporo Technology Center in Sapporo, Hokkaido			
2004/6	Reorganized Shanghai office, and estab. TOREX SEMICONDUCTOR DEVICE (Shanghai) CO., LTD.			
2005/12	Established Taiwan office			
	Opened Kanto West Sales Office in Tachikawa, Tokyo			
2006/3	Kansai branch office moved to Yodogawa-ku, Osaka			
2006/10	Absorbed through merger Torex Device Co., Ltd.			
	As a result of this merger, Device Engineering Co., Ltd. became a wholly owned subsidiary			
2007/2	Established TOREX (HONG KONG) LIMITED			
2007/3	TOREX SEMICONDUCTOR DEVICE (HONG KONG) LTD (currently ISM ASIA LIMITED) shares sold			
2007/4	The Taiwan office was reorganized, and established TOREX SEMICONDUCTOR TAIWAN LTD.			
	Established TOS Device Co., Ltd.			
2008/8	Obtained ISO 9001 certification (head office and all Japan bases)			
2008/9	Opened Tokyo Technical Center in Chuo-ku, Tokyo			
2000/4	Acquired 10% share capital of VIETNAM SEIBI SEMICONDUCTOR CO., LTD. (currently TOREX			
2009/4	VIETNAM SEMICONDUCTOR CO., LTD)			
2000/11	Acquired 80% share capital of VIETNAM SEIBI SEMICONDUCTOR CO., LTD. (currently TOREX			
2003/11	VIETNAM SEMICONDUCTOR CO., LTD), making it a subsidiary			
2010/5	Increased capital of VIETNAM SEIBI SEMICONDUCTOR CO., LTD (currently TOREX VIETNAM			
	SEMICONDUCTOR CO., LTD), raising stake to 92.5%			
2010/9	Kanto West Sales Office consolidated into the head office			
2012/7	Merged Device Engineering Co., Ltd. and TOS Device Co., Ltd., with Device Engineering Co.,			
	Ltd. as the surviving entity			
2014/4	Head office moved to Shinkawa, Chuo-ku, Tokyo			
2014/4				
2014/9	Increased capital of VIETNAM SEIBI SEMICONDUCTOR CO., LTD (currently TOREX VIETNAM			
2015/2	Absorbed through morger Device Engineering Co. Ltd			
2015/5	Absoluted children integer Device Engineering Co., Etc.			
2013/4	VIETNAM SEIRI SEMICONDUCTOR CO. LTD. company name changed to TOREX VIETNAM			
2015/10	Listing designation moved from IASDAO to the TSE Second Section			
2015/10	Capital alliance with PHENITEC SEMICONDUCTOR Corp. made a subsid (51.0% of voting rights)			
2010/4	Onened TOREX LISA Corp. R&D Center in California LISA			
2016/5	Opened Kansai Technology Center in Suita Osaka			
2010/5	Established Nagova Sales Office			
2017/0	Listing designation moved from the TSE Second Section to the TSE First Section			
2010/3	Made PHENITEC SEMICONDUCTOR Corp. a wholly owned subsidiary			
2019/8	Made TOREX VIETNAM SEMICONDUCTOR CO. LTD. a wholly owned subsidiary			
2019/9	Capital Alliance with Cirel Systems Pyt Ltd.			
_010,0	Registered as a remote support department of IATE 16949 certified factory PHENITEC			
	SEMICONDUCTOR Corp. (Kansai Technology Center)			
2020/6	Capital Alliance with Novel Crystal Technology, Inc.			
2020/12	Registered as a remote support department of IATF 16949 (Head Office added)			
Source: YUI	Source: YUHO financial statements, Torex website.			



March 2020 25<sup>™</sup> Anniversary



However, after that, product development did not progress as planned, and due to overlapping with the semiconductor recession, a large amount of debt was accumulated, and the former Torex Semiconductor Co., Ltd. was closed down through special liquidation. The current Torex Semiconductor Co., Ltd. was established in March 1995 by taking over the business related to analog power management IC design and sales. Just 1½ years later, the company established its first overseas base in Singapore in November 1996. Ignoring the fact that the market for battery-powered ultracompact and low-energy consumption power ICs was still small in scale with few market entrants and concerns about being premature, this marked the first step toward developing the Group's global reach today. In 1997, in order to reduce noise for pager wireless communications devices, Torex proposed a counter-intuitive internal oscillation circuit which intentionally sacrificed some efficiency, culminating in launching the XC6373/XC6383 Series of DC/DC converters.

#### TOREX VIETNAM SEMICONDUCTOR CO., LTD.



Over the next 4 years the company established bases in Irvine, California in the US, gaining a presence near Silicon Valley, and in Leicestershire, UK in Europe. Over the following 5 years during the mid-2000s, the company established bases in Shanghai, Taiwan and Hong Kong. Then in April 2009, the company acquired a 10% stake in VIETNAM SEIBI SEMICONDUCTOR CO., LTD. (currently TOREX VIETNAM SEMI-CONDUCTOR CO., LTD), raising its stake to 80% in November 2009, making it a subsidiary. With the increase of mobile devices, many companies began entering the compact power management IC industry. In order to differentiate itself from competitors, Torex began its push toward 'ultra-compact', developing a unique technology known as USP (ultra-small packages). Torex secured its own factory in Vietnam as a USP production base for back-end package assembly.

At the time of the IPO listing its shares on the TSE JASDAQ standard Market in April 2014, PHENITEC SEMICONDUCTOR Corp.. was the largest shareholder with a 19.2% stake. The company successfully moved its listing designation to the TSE Second Section 1½ years later in October 2015, moving up to the TSE First Section in March 2018. The company concluded a capital alliance with PHENITEC SEMICONDUCTOR in April 2016, acquiring a 51.0% stake, making it a subsidiary. Through a capital increase in April 2018, Torex raised its stake in Phenitec to 69.1%. Then in February 2019, the company raised its stake to 100%, making Phenitec a wholly owned subsidiary.

Some may question the meaning of fabless while also having foundry business which comes with high fixed costs, however, management ultimately decided to make the acquisition based on emphasizing stable supply of products to customers. At the time of acquisition, the company had decided to focus on target applications of industrial equipment and automotive, and automotive customers in particular paid close attention to stable supply capability. Also, there is a tendency of external third-party foundries to be reluctant to accept the time-consuming hassle from small-lot trial production for proprietary products. The Group having its own foundry business not only resolves these issues, but since Phenitec has its own customer base, it also does not rely on Torex for orders, and it can maintain stable business operations on its own. Even now Torex accounts for only a small portion of Phenitec sales. The business combination with Phenitec was a watershed milestone in the Group's corporate history. In PART THREE on earnings analysis, we look at why Phenitec is NOT a drag on profitability. The exhibit on the top of the following page shows an organization chart for the 9 principal companies in the TOREX SEMICONDUCTOR Group.



Sessa Investment Research

### **TOREX SEMICONDUCTOR Group Organization Chart**



#### Source: compiled by Sessa Partners from YUHO financial statements

# PHENITEC SEMICONDUCTOR Corp. Manufacturing Facilities: Okayama Head Office Fab



Wafer size	5-inch
Mfg. Capacity	45k pcs/month
Main foundry products	Process rule
Switching diode	≥ 5 <i>µ</i> m
Zener diode	≥ 5 <i>µ</i> m
Shottky barrier diode	≥ 5 <i>µ</i> m
Photo diode	≥ 5 <i>µ</i> m
TVS	≥ 5 <i>µ</i> m
Bipolar transistor	≥ 5 <i>µ</i> m
Course Blooding adapted	

Source: Phenitec website





### Okayama Daiichi (No.1) Fab



Tools and Equipment			
Stepper (g-line and i-line), trench etcher, laser trimming			
PDK available, test • probe available, dicing possible			

Wafer size	5-inch		
Mfg. Capacity	22k wfs/month		

Main foundry products	Process rule
Bipolar transistor	≥ 5 <i>µ</i> m
Bipolar IC	≥ 1.5 <i>µ</i> m
MOSFET	≥ 1.0 <i>µ</i> m

Wafer size	6-inch		
Mfg. Capacity	22k wfs/month		

Main foundry products	Process rule
TVS	≥0.6 <i>µ</i> m
MOSFET	≥ 0.4 <i>µ</i> m
IGBT	≥0.6 <i>µ</i> m
CMOS IC	≥0.6 <i>µ</i> m

Source: Phenitec website

### Kagoshima Fab



Tools and Equipment
Stepper (KrF and i-line), high-energy implant, CMP (W, SiO, Si),
HDP-CVD, DEEP RIE, backside grinding, backside sputter

High-temperature implant, activation annealer, RIE, pre-production



Wafer size	6-inch	
Mfg. Capacity	15k wfs/month	

Main foundry products	Process rule
CMOS IC	≥ 0.35 <i>µ</i> m
MOSFET	≥ 0.2 <i>µ</i> m
IGBT	≥ 0.6 <i>µ</i> m
SiC	≥ 0.6 <i>µ</i> m

Source: Phenitec website



Overview of Foundry Business

3 key considerations for the

(1) Automotive customers in

stable supply capability. The graphic on the right highlights

particular place high priority on

control of quality and delivery.

(2) Many industrial customers

production of custom designs

(outside foundries discourage)

(3) Phenitec has its own customer base, not reliant on Torex. Its largest customer IXYS Corp. (US) accounted for 10.8% of total FY3/21 Group sales.

ask for small-lot trial

acquisition of Phenitec

### Summary of Phenitec's comprehensive foundry solutions services



### **★** Phenitec is the sole provider of foundry service in Japan focused on discrete and CMOS process





### Okayama Plant Integration Project

### Head Office Plant Integration with the Daiichi (No.1) Plant

Since Phenitec's Okayama Plant is divided into the Head Office Fab and the Daiichi (No.1) Fab, it has been hard to raise operational efficiency, and due to the additional requirement of measures to address aging facilities in the Head Office Fab, the company began work on the project to integrate the two fabs in FY3/18. Raising productivity will also be achieved by raising the ratio of 6-inch wafers. The project has taken time since work has progressed without reducing utilization rates, and completion was unavoidably pushed back due to the recent sharp recovery in demand.



Source: company IR materials



### **Integration Effect**

- Continue long-term stable product supply system
- Raise production efficiency by migrating from 5-inch to 6-inch wafers (raise 6-inch ratio from  $24\% \rightarrow 64\%$ )
- Optimize efficiencies with the right equipment and the right layout
- Reduce manufacturing cost through energy-saving plant structure
- Continue to raise quality standards for automotive and industrial equipment applications
- New Fab 4 has precious metal (gold, platinum) processing capability as in the Head Office Fab

### **Head Office Fab**

- Use small diameter (4-inches and below) facilities for development of next-generation power devices
- Utilization at small volume mass production



The Kagoshima Plant is

of next-generation SiC

power devices toward

mass production.

ramping up development



### **Kagoshima Plant Overview and Update**

Start-up and development of the Kagoshima Plant acquired from Yamaha in Oct-2015 appears to be on schedule. At the time of acquisition, the plant started out with zero backlogs since the company only took over the facilities and employees, however since then the company has steadily won new orders, and the plant has begun turning profitable on a single month basis. The graph below shows the trend of the number of prototype products, which is a leading indicator for mass production, and apparently progress is running at a healthy pace.

The Kagoshima Plant, acquired from Yamaha Corp. in October 2015, in addition to being able to handle Group focus automotive applications, serves a key function in business contingency planning (BCP), since it employs similar process equipment used at the Daiichi (No.1) Plant in Okayama, and could take up a portion of the slack in the event of power outage or other production disruption. ISO/TS 16949 from 2009, a technical specification for automotive sector quality management systems, has become one of the most widely used international standards in the global automotive supply chain. ISO/TS 16949, is evolving with the publication of a new global industry standard by the International Automotive Task Force (IATF). On October 3, 2016, IATF 16949: 2016 was published by the IATF, defining the requirements of a Quality Management System for organizations in the automotive industry. The company obtained IATF 16949 certification at the Kagoshima Plant in 2020.

#### Kagoshima Plant Trend of Products by Prototypes and Mass Production

FY3/22 hiking capacity to 18k wfs/month • 3/22 start orders above capacity Power MOSFET (51%) Mass producing new Si power devices Working to mass produce SiC SBDs CMOS (33%) 158 142 **IGBT (6%)** reliable 123 mass TVS (5%) prod-187 179 No. prototypes 128 uction Mass produced **MEMS (4%)** 19.3 20.3 21.3 22.3 Mass production breakdown 3/21



Source: excerpt from 4Q results briefing materials.





**Battery Life** 

170%

Battery Life (Comparison the conventional product is 100)

Ultra Low Power DC/DC

XC9276

Vout

Input Signal

Ultra-low power consumption, small stepdown DC/DC converter XC9276 series wins "ECCJ Chairman's Award" of 2020 **Energy Conservation Grand** Prize in the Product & **Business Model Category** 





**USP** package (ultra-small package)



WLP package (wafer-level package)



### Torex Power Mgt ICs competitive strengths: ultra-compact and energy-saving

The company announced on December 24, 2020 that its step-down DC/DC converter XC9276 Series was awarded the "ECCJ Chairman's Award," FY2020 Energy Conservation Grand Prize in the Product & Business Model category, which has 200nA ultra-low quiescent current and 1.7X longer battery life with output voltage selectable function, by the Energy Conservation Center of Japan (ECCJ).

The XC9276 series greatly improves the efficiency below IOUT=1mA through the current consumption of 200nA. Compared with traditional products, the efficiency of IOUT=10µA is increased by more than 20%. In addition, the newly developed VSET function is used to switch the output voltage. By switching the 2-value output voltage, the XC9276 series reduces power consumption by 41.3% and increases battery life by 1.7 times compared with traditional products. This product is expected to be deployed in products such as small IoT devices and wearable devices that are small and need to be driven for a long time.

**3attery Life** 

Ultra Low Power DC/DC

Conventional Product

IC

Output

Voltage

Logic

Technology of switching between two-value output voltage

Only input signal without external parts, Achieves a function that can switch between binary output voltages.

(2)Output two-value output voltage through input signal



### Technology of ultra-low power

Stop the internal circuit of the IC according to the control status of the IC.Realize ultra-low current consumption.



### Technology of reduce mounting area

The installation area is reduced by reducing the coil inductance value and the IC package area.



Source: excerpts from company website.





### Inductor built-in micro **DC/DC** converters



Note: indexed to FY3/17 = 100.

One of the strengths of Torex and a factor driving growth is aggressive new product development of inductor built-in micro DC/DC converters, which have the properties of 1) ultra-compact, 2) low power consumption, 3) high efficiency and 4) low EMI noise, and different package types emphasize the required property. The graph above shows this category has been growing at +24.3% CAGR over the last 3 years.

The XCL303/XCL304 series below targets high-speed optical transceivers for 5G applications, and it is the first inductor built-in micro DC/DC converter product on the market to handle negative output voltage.



### High-growth focus product: inductor built-in micro DC/DC converters

The micro DC/DC XCL Series is ultra small DC/DC converters that integrate a coil and a control IC using Torex's unique technology, which realize devices that simultaneously achieve space-saving, high efficiency, low noise, high heat dissipation, and low cost.

Wireless and GPS functions are being added to a wide variety of devices, and radiofrequency interference and noise have become key concerns in electrical circuit design. Torex's micro DC/DC XCL Series is optimized to achieve a lower noise than with a discrete DC/DC converter configuration.

Improving power conversion efficiency is a key point in miniaturizing a power circuit. When semiconductor and electronic components are made smaller, the resistance component increases and the loss appears as heat generation. The micro DC/DC XCL Series reduces the loss of efficiency that accompanies miniaturization.



current

Low cost

High

withstand voltages



Source: excerpt from company website.

### Inductor built-in micro DC/DC converter target markets / applications

Personal Electronics	Industrial Equipment	Automotive Equipment	Medical Equipment
Wireless earphones	5G optical transcievers	Drive recorders	Blood pressure monitors
Wearables	Microcontroller boards	ETC onboard units	Blood sugar monitors
Beauty care products	Sensor modules	Car navigtion	Fingertip pulse oximeters
Bluetooth, WiFi, GPS modules	Camera modules	AV main units	Healthcare equipment
	Home security	Camera and sensor modules	
	POS terminals	Keyless entry	
	IoT device modules	Power sliding doors	
		Sub displays	

0

 $\triangle$ 

0

 $\Delta$ 

0

0





### TOREX SEMICONDUCTOR Group Global Sales, Manufacturing and R&D Network: → 8 bases in Japan, 9 bases overseas



Source: company IR materials

### Brief explanation about geographic breakdowns of Group net sales

The table on the following page shows three different classifications for regional sales breakdowns. The top rung is official reporting segments. In Japan, Torex is engaged in the manufacture and sales of power mgt. ICs, and Phenitec accepts orders, manufactures, ships, and sells wafers. The three overseas segments are organized around the 6 local sales subsidiaries shown in the organization chart on the top of P21.

"Design-in" base sales reflect where electronic devices etc. equipped with company products were planned and designed, and in which orders were actually won. It is used as an important analytical tool for management decision making on business strategy.

The lower rung is regional sales based on the location of the customer.

### **TOREX SEMICONDUCTOR Group Number of Employees**

FY3/17	FY3/18	ΥοΥ	FY3/19	ΥοΥ	FY3/20	YoY	FY3/21	YoY
act	act	chg	act	chg	act	chg	act	chg
981	982	1	1,017	35	1,016	(1)	1,016	0
799	799	0	819	20	830	11	831	1
160	159	(1)	174	15	167	(7)	166	(1)
14	14	0	15	1	10	(5)	11	1
8	10	2	9	(1)	9	0	8	(1)
160	159	(1)	168	9	172	4	175	3
	FY3/17 act 981 799 160 14 8 	FY3/17         FY3/18           act         act           981         982           799         799           160         159           14         14           8         10           160         159	FY3/17         FY3/18         Y0Y           act         act         chg           981         982         1           799         799         0           160         159         (1)           14         14         0           8         10         2           160         159         (1)	FY3/17         FY3/18         YoY         FY3/19           act         act         chg         act           981         982         1         1,017           799         799         0         819           160         159         (1)         174           14         14         0         15           8         10         2         9           160         159         (1)         168	FY3/17         FY3/18         YoY         FY3/19         YoY           act         act         chg         act         chg           981         982         1         1,017         35           799         799         0         819         20           160         159         (1)         174         15           14         14         0         15         1           8         10         2         9         (1)           160         159         (1)         168         9	FY3/17         FY3/18         YoY         FY3/19         YoY         FY3/20           act         act         chg         act         chg         act           981         982         1         1,017         35         1,016           799         799         0         819         20         830           160         159         (1)         174         15         167           14         14         0         15         1         10           8         10         2         9         (1)         9           160         159         (1)         168         9         172	FY3/17         FY3/18         YoY         FY3/19         YoY         FY3/20         YoY           act         act         chg         act         chg         act         chg           981         982         1         1,017         35         1,016         (1)           799         799         0         819         20         830         11           160         159         (1)         174         15         167         (7)           14         14         0         15         1         100         (5)           8         10         2         9         (1)         9         0           160         159         (1)         168         9         172         4	FY3/17         FY3/18         YoY         FY3/19         YoY         FY3/20         YoY         FY3/21           act         act         chg         act         chg         act         chg         act         act

Source: compiled by Sessa Partners from YUHO financial statements.



### \*Design-in base sales

effectively scale back the large weight of China mainly due to final assembly of electronic products there, aiming to reflect business in 'real terms.'

Tokyo Sales Division:
6F DAIHO ANNEX
(also Osaka and Nagoya)
Asia Sales Offices:
Shanghai, Hong Kong,
Taipei, Singapore
UK Sales Office:
Leicestershire
US Sales Office:
Irvine, California

[J-GAAP]	FY3/17	FY3/18	ΥοΥ	FY3/19	YoY	FY3/20	YoY	FY3/21	YoY
JPY mn, %	act	act	pct	act	pct	act	pct	act	pct
Reported segments									
Net sales	21,560	23,997	11.3	23 <i>,</i> 897	(0.4)	21,501	(10.0)	23,713	10.3
• Japan	14,611	16,772	14.8	16,935	1.0	14,778	(12.7)	16,963	14.8
• Asia	5,551	5,696	2.6	5,444	(4.4)	5,461	0.3	5,527	1.2
• Europe	809	892	10.2	880	(1.3)	718	(18.4)	698	(2.8)
• N America	588	637	8.2	638	0.1	545	(14.6)	526	(3.4)
Net sales	100.0%	100.0%	_	100.0%	_	100.0%	_	100.0%	_
• Japan	67.8%	69.9%	_	70.9%	_	68.7%	_	71.5%	_
• Asia	25.7%	23.7%	_	22.8%	_	25.4%	_	23.3%	_
• Europe	3.8%	3.7%	—	3.7%	_	3.3%	_	2.9%	_
N America	2.7%	2.7%	_	2.7%	_	2.5%	_	2.2%	—
*Design-in base									
Net sales	21,560	23,997	11.3	23,897	(0.4)	21,501	(10.0)	23,713	10.3
• Japan	15,867	18,124	14.2	18,193	0.4	16,026	(11.9)	17,986	12.2
• Asia	3,199	3,330	4.1	3,312	(0.5)	3,405	2.8	3,611	6.0
• Europe	1,471	1,491	1.3	1,431	(4.0)	1,212	(15.3)	1,189	(1.9)
• N America	1,023	1,052	2.9	961	(8.6)	859	(10.7)	927	7.9
Net sales	100.0%	100.0%	_	100.0%	_	100.0%	_	100.0%	_
• Japan	73.6%	75.5%	_	76.1%	_	74.5%	_	75.8%	_
• Asia	14.8%	13.9%	—	13.9%	—	15.8%	_	15.2%	_
• Europe	6.8%	6.2%	_	6.0%	_	5.6%	_	5.0%	_
N America	4.7%	4.4%	—	4.0%	—	4.0%	_	3.9%	-
By customer location									
Net sales	21,560	23,997	11.3	23,897	(0.4)	21,501	(10.0)	23,713	10.3
• Japan	6,156	6,024	(2.1)	6,687	11.0	6,865	2.7	6,698	(2.4)
• China	7,334	8,209	11.9	8,159	(0.6)	7,326	(10.2)	8,180	11.7
• Taiwan	2,339	3,047	30.3	2,575	(15.5)	2,496	(3.1)	3,413	36.7
<ul> <li>N America</li> </ul>	3,727	4,456	19.6	4,203	(5.7)	2,904	(30.9)	3,530	21.6
• Other	2,004	2,261	12.8	2,274	0.6	1,910	(16.0)	1,893	(0.9)
Net sales	100.0%	100.0%	_	100.0%	_	100.0%	_	100.0%	_
• Japan	28.6%	25.1%	_	28.0%	_	31.9%	_	28.2%	_
• China	34.0%	34.2%	-	34.1%	_	34.1%	_	34.5%	_
• Taiwan	10.8%	12.7%	_	10.8%	_	11.6%	_	14.4%	_
<ul> <li>N America</li> </ul>	17.3%	18.6%	-	17.6%	_	13.5%	_	14.9%	_
• Other	9.3%	9.4%	_	9.5%	_	8.9%	_	8.0%	_

Geographic Sales Breakdown: As Reported, Design-in Base and by Customer Location

Source: compiled by Sessa Partners from YUHO financial statements.











### **PART THREE:**

Earnings Trend, FY12/21 Outlook and New MTP

### Phenitec Acquisition Impact on Margins

In PART TWO we covered the background history and updated status of the Torex Semiconductor Group, and its unique business model of fabless power management IC design, manufacture and sales of Torex combined with the sole Japan foundry service of original and custom discrete products of Phenitec. The key to understanding growth trends and profitability of the group is understanding each of these two core building blocks separately.

### **OPM Comparison by Torex Parent and Phenitec Contribution**

[J-GAAP]	FY3/17	FY3/18	YoY	FY3/19	YoY	FY3/20	YoY	FY3/21	YoY
JPY mn, %	act	act	pct	act	pct	act	pct	act	pct
Net sales	21,560	23,997	11.3	23,897	(0.4)	21,501	(10.0)	23,713	10.3
Gross profit	5,900	7,177	21.6	6,494	(9.5)	5,452	(16.0)	5,959	9.3
GPM	27.4%	29.9%		27.2%		25.4%		25.1%	
SG&A expenses	4,649	4,964	6.8	4,943	(0.4)	4,774	(3.4)	4,750	(0.5)
ratio to sales	21.6%	20.7%		20.7%		22.2%		20.0%	
EBITDA	2,470	3,147	27.4	2,636	(16.2)	1,990	(24.5)	2,418	21.5
ratio to sales	11.5%	13.1%		11.0%		9.3%		10.2%	
Operating profit	1,251	2,212	76.8	1,551	(29.9)	678	(56.3)	1,209	78.3
ОРМ	5.8%	9.2%		6.5%		3.2%		5.1%	
Torex parent sales	10,181	10,168	(0.1)	10,104	(0.6)	9,663	(4.4)	9 <i>,</i> 605	(0.6)
Phenitec contribution	11,378	13,828	21.5	13,792	(0.3)	11,837	(14.2)	14,107	19.2
Torex parent OP	680	633	(6.9)	646	2.1	453	(29.9)	516	13.9
Phenitec contribution	571	1,579	176.5	904	(42.7)	225	(75.1)	693	208.0
Torex parent OPM (%)	6.7%	6.2%		6.4%		4.7%		5.4%	
Phenitec contribution	5.0%	.11.4%		6.6%		1.9%		4.9%	
Сарех	925	1,150	24.4	3,324	188.9	1,497	(55.0)	1,179	(21.2)
Depreciation	1,219	934	(23.4)	1,085	16.2	1,312	20.9	1,208	(7.9)
R&D expense	229	405	76.9	357	(11.9)	403	12.9	457	13.4

Source: compiled by Sessa Partners from TANSHIN financial statements and IR results briefing materials

### Cost Structure Before and After the Phenitec Acquisition



Source: compiled by Sessa Partners from TANSHIN financial statements





The table on the previous page summarizes the trend of consolidated net sales and profits for the Torex Semiconductor Group. As noted in PART TWO, Torex concluded a capital alliance with its top shareholder Phenitec, acquiring a majority 51% stake on April 1, 2016. Therefore, results through FY3/16 are for Torex Semiconductor, and from FY3/17 onward are for the combined group. Although not required disclosure in officially submitted financial statements, results briefing presentation materials provide invaluable supplemental disclosures giving net sales and OP breakdowns by Torex and the Phenitec contribution which exclude intra-company transactions.

First, let's examine the cost structure before and after the business combination. In the 3 years through FY3/16, as a fabless design house, Torex had average GPM of 47.4%, a high level absent the fixed costs associated with plant operations including depreciation. In the 3 years from FY3/17 onward, average GPM dropped to 28.2% reflecting the fixed costs associated with Phenitec's foundry operations.

At the same time, in the 3 years through FY3/16, Torex had an average SG&A ratio of 34.4%, reflecting higher R&D and head office administration-related costs. In the 3 years from FY3/17 onward, the average SG&A ratio dropped to 21.0%, reflecting lower R&D and head office administration-related costs of Phenitec.

Ultimately, average OPM in the 3 years through FY3/16 of 13.0% declined to 7.2% in the 3 years from FY3/17 onward, but that does not necessarily mean that profitability of Phenitec is a drag on overall profitability. From the table we can see that in FY3/18, Phenitec contribution OPM reached 11.4%, well above the 6.2% for Torex. Given the plant operations specific to Phenitec, it is clear that profitability is driven in large part by capacity utilization rates. In FY3/18, note that Phenitec contribution revenue rose by +21.5% YoY, an increase of ¥2,450 million. Of that increase, roughly ¼ is attributed to its major North American customer IXYS Corporation, a California-based specialist in power semiconductors, discrete MOSFETs and IGBT modules, focused on automotive and industrial applications, which itself was acquired by Littelfuse Corporation in 2018. The sharp boost in utilization rates drove profitability significantly higher.

Phenitec of OP and OI	Phenitec contribution OP and OPM:										
1Q 3/19	¥487mn	13.1%									
2Q 3/19	¥413mn	11.7%									
4Q 3/21	¥415mn	11.3%									

The key takeaway is that Phenitec profitability is largely a function of capacity utilization rates, and on any given quarter, OPM can be significantly higher than Torex. Other factors can include a spike in raw materials cost, such as the recent spike in gold prices. The table and graph on the following page illustrate this mechanism clearly. The same phenomenon occurred in 4Q 3/21. As noted at the top of the cover page, high growth in Group net sales and profits was temporarily interrupted by the significant slowdown in global trade in CY2019 due to escalation of the US-China tariff dispute, followed by initial adverse impact on global economic activities under the pandemic during 1H 2020. From the table, we can see that Phenitec contribution OP in the two quarters before the outbreak of the US-China tariff war was ¥487mn and ¥413mn (1Q and 2Q 3/19), with double-digit OPM respectively. In the bar chart below the master table, Phenitec contribution OP is designated by the yellow bars.

After the tariff dispute escalated, we can see that Phenitec contribution OP deteriorated rapidly with the coinciding decline in capacity utilization rates. Note that it posted an operating loss in 4Q 3/19, when Japan exports to China turned negative YoY. As noted in PART ONE, we have found Japan exports to China to be a reliable proxy for the general health of the global electronics supply chain. The bar chart shows that Phenitec contribution OP continued to struggle for 9 quarters. Then in 4Q 3/21, in part due to strong orders from its major North American client IXYS Corporation, the recovery in utilization rates supported the significant recovery to ¥415mn, with OPM vaulting back to 11.3%. For reference, 4Q 3/21 OPM for Torex was only 3.5%.

JPY mn, %	1Q 3/19	2Q 3/19	3Q 3/19	4Q 3/19	1Q 3/20	2Q 3/20	3Q 3/20	4Q 3/20	1Q 3/21	2Q 3/21	3Q 3/21	4Q 3/21	1Q 3/22
	act	act	act	act	act	act	act	act	act	act	act	act	act
Net sales	6,203	6,266	6,074	5,353	4,797	5,534	5,598	5,571	5,858	5,550	5,762	6,541	7,013
YoY	8.6	2.8	0.6	(13.0)	(22.7)	(11.7)	(7.8)	4.1	22.1	0.3	2.9	17.4	19.7
Phenitec contrib.	3,727	3,539	3,642	2,884	2,595	2,885	3,035	3,322	3,688	3,330	3,411	3,678	4,011
YoY	15.1	0.7	4.4	(19.6)	(30.4)	(18.5)	(16.7)	15.2	42.1	15.4	12.4	10.7	8.8
• Torex	2,476	2,727	2,432	2,469	2,202	2,649	2,563	2,249	2,170	2,220	2,351	2,864	3,002
YoY	0.1	5.7	(4.6)	(3.7)	(11.1)	(2.9)	5.4	(8.9)	(1.5)	(16.2)	(8.3)	27.3	38.3
Gross profit	1,921	1,892	1,530	1,151	1,269	1,422	1,446	1,315	1,325	1,210	1,606	1,817	1,942
GPM	31.0%	30.2%	25.2%	21.5%	26.5%	25.7%	25.8%	23.6%	22.6%	21.8%	27.9%	27.8%	27.7%
SG&A	1,246	1,216	1,218	1,263	1,191	1,170	1,241	1,172	1,129	1,146	1,174	1,301	1,306
Ratio to sales	20.1%	19.4%	20.1%	23.6%	24.8%	21.1%	22.2%	21.0%	19.3%	20.6%	20.4%	19.9%	18.6%
Depreciation	195	239	300	351	305	317	335	355	269	278	325	336	283
ҮоҮ	(11.8)	4.4	29.9	38.7	56.4	32.6	11.7	1.1	(11.8)	(12.3)	(3.0)	(5.4)	5.2
EBITDA	870	915	612	239	384	568	540	498	464	343	758	851	919
YoY	28.7	5.8	(21.5)	(71.0)	(55.9)	(37.9)	(11.8)	108.4	21.1	(39.6)	40.4	70.9	98.1
Ratio to sales	14.0%	14.6%	10.1%	4.5%	8.0%	10.3%	9.6%	8.9%	7.9%	6.2%	13.2%	13.0%	13.1%
Operating profit	675	676	311	(112)	78	252	204	144	195	65	433	515	636
YoY	48.4	6.5	(43.5)	TR	(88.4)	(62.7)	(34.4)	ТВ	148.9	(74.2)	112.3	257.6	226.2
ОРМ	10.9%	10.8%	5.1%	-2.1%	1.6%	4.6%	3.6%	2.6%	3.3%	1.2%	7.5%	7.9%	9.1%
<ul> <li>Phenitec contrib.</li> </ul>	487	413	186	(182)	59	4	78	84	122	(33)	189	415	366
YoY	60.7	(19.6)	(46.1)	TR	(87.9)	(99.0)	(58.1)	ТВ	106.8	TR	142.3	394.0	200.0
OPM	13.1%	<mark>11.7%</mark>	5.1%	-6.3%	2.3%	0.1%	2.6%	2.5%	3.3%	-1.0%	5.5%	<mark>11.3%</mark>	9.1%
• Torex	188	263	125	70	19	248	126	60	73	98	244	101	270
YoY	23.7	117.4	(39.0)	(54.8)	(89.9)	(5.7)	0.8	(14.3)	284.2	(60.5)	93.7	68.3	269.9
OPM	7.6%	<mark>9.6%</mark>	5.1%	2.8%	0.9%	9.4%	4.9%	2.7%	3.4%	4.4%	10.4%	3.5%	<mark>9.0%</mark> •*
Ordinary profit	924	819	227	(150)	11	268	240	157	180	(3)	348	680	676
ҮоҮ	98.3	27.8	(62.5)	TR	(98.8)	(67.3)	5.7	ТВ	16.4x	TR	45.0	333.1	275.6
Profit ATOP	496	469	123	(39)	12	146	133	127	168	(11)	230	545	476
YoY	112.0	75.7	(58.0)	TR	(97.6)	(68.9)	8.1	ТВ	13.9x	TR	72.9	329.1	183.3

**TOREX SEMICONDUCTOR Quarterly Consolidated Earnings** 

Source: compiled by Sessa Partners from company IR results briefing presentation materials.



Torex posted the highest quarterly sales since listing due to the booming semiconductor market which has continued from 2H last term, with all regions posting strong performance.

Phenitec posted growth in sales and profits driven by strong orders boosting utilization rates, posting the highest sales since becoming a consolidated subsidiary.

### Torex posted strong results in all regions, and recorded the highest sales since listing



Sessa Partners



			•		•		•						
JPY mn, %	1Q 3/19	2Q 3/19	3Q 3/19	4Q 3/19	1Q 3/20	2Q 3/20	3Q 3/20	4Q 3/20	1Q 3/21	2Q 3/21	3Q 3/21	4Q 3/21	1Q 3/22
by Application													
Torex sales	2,476	2,727	2,432	2,469	2,202	2,649	2,563	2,249	2,170	2,220	2,351	2,864	3,002
<ul> <li>Industrial equipt.</li> </ul>	966	1,063	945	953	784	912	933	834	872	763	805	1,064	1,033
Automotive equipt.	381	384	362	408	350	615	457	327	241	249	352	398	400
<ul> <li>Medical equipt.</li> </ul>	36	26	26	37	25	21	29	43	73	44	43	66	49
Wearable equipt.	71	74	37	56	53	66	54	47	50	100	100	112	86
Other	1,022	1,180	1,062	1,015	990	1,035	1,090	998	934	1,064	1,051	1,224	1,434
ΥοΥ													
Torex sales	0.1	5.7	(4.6)	(3.7)	(11.1)	(2.9)	5.4	(8.9)	(1.5)	(16.2)	(8.3)	27.3	38.3
<ul> <li>Industrial equipt.</li> </ul>	9.8	14.3	(0.1)	(2.0)	(18.8)	(14.2)	(1.3)	(12.5)	11.2	(16.3)	(13.7)	27.6	18.5
Automotive equipt.	(3.5)	(3.3)	(18.1)	(13.9)	(8.1)	60.2	26.2	(19.9)	(31.1)	(59.5)	(23.0)	21.7	66.0
<ul> <li>Medical equipt.</li> </ul>	80.0	(13.3)	(23.5)	54.2	(30.6)	(19.2)	11.5	16.2	192.0	109.5	48.3	53.5	(32.9
Wearable equipt.	10.9	19.4	(31.5)	5.7	(25.4)	(10.8)	45.9	(16.1)	(5.7)	51.5	85.2	138.3	72.0
Other	788.7	(45.4)	(1.0)	(2.5)	(3.1)	(12.3)	2.6	(1.7)	(5.7)	2.8	(3.6)	22.6	53.5
by Region													
Torex D-in* sales	2,476	2,727	2,432	2,469	2,202	2,649	2,563	2,249	2,170	2,220	2,351	2,864	3,002
• Japan	1,086	1,159	1,070	1,086	950	1,090	1,104	1,043	896	895	958	1,129	1,160
• Asia	791	896	818	807	724	1,001	980	700	781	849	876	1,105	1,197
• Europe	345	402	304	379	305	329	268	310	259	242	304	384	383
North America	254	270	240	197	223	229	211	196	234	234	213	246	262
ΥοΥ													
Torex D-in* sales	0.1	5.7	(4.6)	(3.7)	(11.1)	(2.9)	5.4	(8.9)	(1.5)	(16.2)	(8.3)	27.3	38.3
• Japan	8.8	6.5	0.4	(5.1)	(12.5)	(6.0)	3.2	(4.0)	(5.7)	(17.9)	(13.2)	8.2	29.5
• Asia	(0.3)	13.0	(8.7)	(4.7)	(8.5)	11.7	19.8	(13.3)	7.9	(15.2)	(10.6)	57.9	53.3
• Europe	(19.0)	0.5	(7.9)	13.1	(11.6)	(18.2)	(11.8)	(18.2)	(15.1)	(26.4)	13.4	23.9	47.9
North America	(1.2)	(10.0)	(6.6)	(17.2)	(12.2)	(15.2)	(12.1)	(0.5)	4.9	2.2	0.9	25.5	12.0

#### Torex Sales Trend by Application and Design-in based\* Region with Heat Map

\*Note: Torex 'Design-in' based sales = regional sales adjusted on orders received basis.

### FY3/20 Results

As mentioned earlier, due to escalation of the tariff dispute between the US and China resulting in significant slowdown in global trade, FY3/20 was a difficult year with net sales -10.0% and OP -56.3%, revising down full-term guidance at 1H results, and still posting a slight shortfall. However, to be fair, FY3/20 results could more accurately be described as a series of underlying successes in the face of a truly severe external environment.

As explained in PART ONE, understanding the trend in demand by applications is key to grasping what is actually happening. Parent Torex sales in FY3/20 declined -4.4% YoY. Sales for the two focus growth applications were INDUSTRIAL EQUIPT. -11.8% and AUTOMOTIVE EQUIPT. +13.9%. Weakness in industrial was mainly seen in surveillance cameras, satellite communications and FA-related. Strength in automotive in the 2Q and 3Q (see table above) was attributed to China's vertical ramp-up of ETC nationwide, and high growth in drive recorders in Japan. This reflected one of the company's strengths as a dedicated small and nimble PMIC supplier despite the tough market.

Phenitec sales declined -13.9%. Largely due to the sharp decline in INDUSTRIAL EQUIPT. -38.4%. Looking at the breakdown of the -56.3% decline in OP, by company it was Torex -29.9% and Phenitec -75.1%, which was attributed to the decline in utilization rates as well as increase in depreciation associated with the Okayama Plant integration project. The real noteworthy success was conducting a 5.2% share buyback, hiking the dividend, and paying down LT loans, all while advancing large-scale capex, with net cash still accounting for 25% of net assets, and healthy equity ratio of 67.1%.

Despite the downturn, or perhaps more accurately in response to it, the Board of Directors approved a 5.2% share buyback during FY3/20. This highlights the importance of the Chairman of Phenitec and the President of Torex among the top 10 shareholders.





### FY3/21 Results

The breakdown of the +10.3% increase in net sales by company was Torex -0.6%, in part attributed to the reactionary decline in automotive (see table on the previous page) and Phenitec +19,.2%, attributed to the sharp recovery in industrial orders from its major North American client as well as China. The breakdown of the +78.3% increase in OP by company was Torex +13.9%, attributed to successfully controlling SG&A, and Phenitec +208% on higher utilization rates and lower than expected depreciation.

The gold price spiked to over \$2,000/oz during the 2Q, raising raw materials costs. Although forex losses increased in the 3Q due to the strong yen, depreciation expense came in lower than initially planned due to strong orders and busy utilization rates forcing the company to push out completion of the Daiichi Plant integration project into 1H FY3/22. The yen depreciated significantly during the 4Q.



#### Phenitec\*\* Sales Trend by Application and Region with Heat Map

JPY mn, %	1Q 3/19	2Q 3/19	3Q 3/19	4Q 3/19	1Q 3/20	2Q 3/20	3Q 3/20	4Q 3/20	1Q 3/21	2Q 3/21	3Q 3/21	4Q 3/21	1Q 3/22
by Application	ĺ			ĺ									
Phenitec** sales	4,136	3,973	4,075	3,268	2,983	3,251	3,435	3,628	3,982	3,703	3,732	4,077	4,536
<ul> <li>Industrial equipt.</li> </ul>	759	705	1,100	698	408	412	493	696	911	630	588	653	676
Automotive equipt.	908	873	923	856	876	921	892	915	838	738	869	942	1,044
<ul> <li>Medical equipt.</li> </ul>	98	63	145	84	70	48	54	116	60	32	34	39	36
• Other	2,371	2,332	1,907	1,630	1,629	1,870	1,996	1,901	2,173	2,303	2,241	2,443	2,780
ΥοΥ													
Phenitec** sales	14.9	<b>1.3</b>	5.1	(17.6)	(27.9)	(18.2)	(15.7)	11.0	33.5	13.9	8.6	12.4	13.9
<ul> <li>Industrial equipt.</li> </ul>	(15.3)	(8.7)	29.4	(20.3)	(46.2)	(41.6)	(55.2)	(0.3)	123.3	52.9	19.3	(6.2)	(25.8)
Automotive equipt.	49.1	11.6	9.8	0.0	(3.5)	5.5	(3.4)	6.9	(4.3)	(19.9)	(2.6)	3.0	24.6
<ul> <li>Medical equipt.</li> </ul>	22.5	(52.6)	70.6	42.4	(28.6)	(23.8)	(62.8)	38.1	(14.3)	(33.3)	(37.0)	(66.4)	(40.0)
Other	17.7	4.4	(9.3)	(25.0)	(31.3)	(19.8)	4.7	16.6	33.4	23.2	12.3	28.5	27.9
by Region													
Phenitec** sales	4,136	3,973	4,075	3,268	2,983	3,251	3,435	3,628	3,982	3,703	3,732	4,077	4,536
• Japan	1,479	1,362	1,356	1,332	1,346	1,410	1,427	1,403	1,280	1,277	1,307	1,654	1,983
• Asia	1,019	1,070	750	467	495	661	803	805	914	869	1,088	1,193	1,118
• Europe	198	182	204	205	199	224	261	236	268	244	194	183	230
<ul> <li>North America</li> </ul>	1,440	1,359	1,765	1,264	943	956	944	1,184	1,520	1,313	1,143	1,047	1,205
ΥοΥ													
Phenitec** sales	14.9	1.3	5.1	(17.6)	(27.9)	(18.2)	(15.7)	11.0	33.5	13.9	8.6	12.4	13.9
• Japan	27.5	5.6	8.2	1.9	(9.0)	3.5	5.2	5.3	(4.9)	(9.4)	(8.4)	17.9	54.9
• Asia	25.0	17.8	(23.9)	(53.3)	(51.4)	(38.2)	7.1	72.4	84.6	31.5	35.5	48.2	22.3
• Europe	8.8	(20.9)	7.4	25.8	0.5	23.1	27.9	15.1	34.7	8.9	(25.7)	(22.5)	(14.2)
North America	(0.1)	(9.0)	21.7	(15.5)	(34.5)	(29.7)	(46.5)	(6.3)	61.2	37.3	21.1	(11.6)	(20.7)

\*\*Note: Phenitec sales include intra-company transactions with Torex. Classifications subject to change.



[J-GAAP]	FY3/21	YoY	FY3/22	YoY	FY3/22	YoY	AMT	РСТ	FY3/24	2Y	FY3/26	2Y
JPY mn, %	act	pct	init CE	pct	revised	pct	CHG	CHG	МТР	CAGR	MTP	CAGR
Net sales	23,713	10.3	26,000	9.6	28,500	20.2	2,500	9.6	30,000	7.4	35,000	8.0
EBITDA	2,418	21.5	3,549	46.8	4,169	72.4	620	17.5				
ratio to sales	10.2%		13.7%		14.6%							
Operating profit	1,209	78.3	2,000	65.4	2,500	106.7	500	25.0	3,000	22.5	4,000	15.5
OPM	5.1%		7.7%		8.8%				10.0%		11.4%	
Ordinary profit	1,206	78.4	2,000	65.8	2,500	107.3	500	25.0				
ratio to sales	5.1%		7.7%		8.8%							
Profit ATOP	934	123.6	1,400	50.0	1,750	87.4	350	25.0				
ratio to sales	3.9%		5.4%		6.1%							
Сарех	1,179	(21.2)	2,019	71.2	2,630	123.1	611	30.3				
Depreciation	1,208	(7.9)	1,549	28.2	1,669	38.1	120	7.7				
R&D expense	457	13.4	504	10.3	_							
EPS (¥)	85.42		127.97		159.96							

### **TOREX SEMICONDUCTOR Revised FY3/22 Conslidated Financial Forecasts**

Source: compiled by Sessa Partners from IR results briefing materials

### **Balance of Borrowings from Main Lending Institutions**

JPY mn, %	FY3/17	FY3/18	ΥοΥ	FY3/19	YoY	FY3/20	ΥοΥ	FY3/21	YoY
	act	act	pct	act	pct	act	pct	act	pct
Chugoku Bank	5,465	4,488	(17.9)	4,331	(3.5)	3 <i>,</i> 972	(8.3)	5,842	47.1
SMBC	450	351	(22.0)	251	(28.5)	451	79.7	831	84.3
Mizuho Bank	175	139	(20.6)	88	(36.7)	225	155.7	420	86.7

Source: compiled by Sessa Partners from AGM Notices of Convocation documents.

The sheer speed of the turnaround in FY3/21 can best be illustrated by the exhibit on P3 of new 5-year MTP targets just released in February along with the 3Q upward revision, only to see full-term guidance revised up again in the 4Q, along with significantly higher forecasts for FY3/22. These upward revisions for FY3/21 and FY3/22 overlayed on the initial 5-year MTP targets would imply a decline in FY3/23, which of course the company does not expect. Initial company estimates for FY3/22 are for consolidated net sales +9.6%, OP +65.4% and OPM rising from  $5.1\% \rightarrow 7.7\%$ . MTP targets include raising OPM to 10.0% in FY3/24 (year 3) and 11.4% in FY3/26 (year 5).

The new MTP promotes 'green transformation' through promoting power-saving circuits, reducing mounting board area and promoting low power-loss devices that suppress heat generation. The parent will continue to focus on developing high value-added power management ICs, including further share expansion of inductor built-in micro DC/DC converters, products specialized for 5G/IoT, solutions for solid-state and semi solid-state batteries, ultra-compact large-capacity packages, etc. Initiatives for Phenitec include development of silicon-based power devices and compound semiconductors at Kagoshima, and thorough measures for manufacturing cost reduction, following completion of the Daiichi Plant integration project at Okayama.







### **PART FOUR:**

Key Growth Drivers: 5G / Industrial IoT, EV / Connected Cars / ADAS, Next-gen Power Devices

#### 3 Key Features of 5G:

- higher speed and capacity
- higher reliability / lower
- latency (instantaneous)

supports many simultaneous

connections

#### 5G / Industrial IoT

5G NR (New Radio) is the new radio access technology (RAT) developed by 3GPP (consortium of standards organizations which develop protocols for mobile telecommunications) for the fifth-generation mobile network, designed to be the global standard for the air interface of 5G networks. 5G NR uses two frequency ranges: Frequency Range 1 (FR1), including sub-6 GHz frequency bands, and Frequency Range 2 (FR2), including frequency bands in the mmWave range (24–100 GHz).

Mobile communication systems tend to evolve into a new generation every ten years on average, along with the evolution of mobile phones and the increase in data traffic. Mobile communication standards started with analog system 1G used in the 1980s. However, with the advance of 2G digital systems in the 1990s, data communication became more widespread, especially email. With the arrival of 3G in the 2000s, data communication speeds improved significantly, and it was during this period that communication standards were unified globally. The 4G LTE (Long Term Evolution) technology has become a strong tailwind for smartphones, which are now in widespread use.

Next generation 5G is characterized by three major features: ① enhanced Mobile Broadband (eMBB: ultra-high speed, larger capacity), ② URLLC (Ultra-Reliable and Low Latency Communications), and ③ mMTC (massive Machine Type Communication: multiple simultaneous connections). The maximum speeds offered by 5G are expected to be more than ten times faster than the current 4G standard. 5G standard specification Release 17, which includes enhancements to mMTC, was due to be completed in mid-2021, but was delayed due to the impact of the COVID-19 and is now scheduled to be completed in June 2022 (see graph on next page).

### Evolution of Mobile Communications by Generation



Source: "Electronic Components and Materials for 5G" (March 2021) compiled by Uzabase.


## Development of 5G Standardization by 3GPP (3rd Generation Partnership Project)

2016	2017	2018	2019	2020	2021	2022
<b>Release 14*</b> (Study of 5G, Spe	ecifications)					
	Release 15: 5G P • Determined eau • Established spe • eMBB	<b>hase 1</b> rly specs for 5G ecs for NSA/SA mod	els			
		Release 16: 5G P • Determined a fu • URLLC and IoT • Determined spu • Completed in J	hase 2 ull specification for compatibility adde ecs for lower latenc uly 2020	5G d y and higher power	refficiency	
IMT Vision (Se • Determined • Requirement	ptember 2015) by ITU-R ts for 5G		Rela • Cc • Ex • Pl	ease 17 onsider 52.6GHz+ sp pand functionality anned to be comple	pectrum for mMTC, etc. eted within 2021	

Source: "Electronic Components and Materials for 5G" (March 2021) compiled by Uzabase.

In order to enable higher speeds and larger volumes of data, 5G uses high-frequency millimetre waves. High frequency spectrum has its own disadvantages, such as a higher atmospheric attenuation and susceptibility to obstructions such as buildings. In the past, macrocells were used to cover a wide area, but a stable communication network for 5G can only be achieved by installing a large number of small cells which have relatively narrow coverage but low power consumption and small size.

## Example of 5G Infrastructure Using Small Cells



#### Source: "Electronic Components and Materials for 5G" (March 2021) compiled by Uzabase.



5G cellular repeater





★ Massive MIMO is a technology that utilizes more than a hundred antennas (as opposed to just a few in previous generations) and allocates a dedicated wave to each user, which is already commercially available.

**Beamforming** is a technique for shifting high-frequency millimetre-wave signals along with the movement of the user, to be used in combination with Massive MIMO.

### Key technologies which enable 5G

Technology	Main Features	Details
Massive MIMO	Larger capacity, ultra-high speed	While conventional MIMO (Multiple-Input and Multiple-Output) technology increases communication quality via 2 to 4 antennas on the transmitting and the receiving side, Massive MIMO allows for more than 100 antennas to be installed. With that, a base station can receive and transmit a large number of signals simultaneously, which should improve the capacity of the network. On the other hand, there is a higher chance of interference if the signals of two complex antennas cross.
Beamforming	Ultra-high speed and reliability	This technology directs a signal in a particular direction by adjusting the power and the phase of a wave transmitted from an antenna. This enables multiple devices to use the same frequency. Implementing this technology in Massive MIMO would decrease interference and increase speed.
Full Duplex	Larger capacity	Full Duplex allows the receiving device to both transmit and receive signals simultaneously, as opposed to conventional technology where only one can be done at a time. With this implemented, the usable frequency band would essentially double, and the capacity of the entire wireless network would double as well.
Heterogeneous Network	Larger capacity	Improves the capacity of the entire network via small cells placed to cover narrow areas where traffic is particularly heavy, within the wider coverage zone of macrocells.
Dual Connectivity (C/U Plane Split)	Ultra-high speed, larger capacity	This technology splits the transmission of signalling protocols traffic (C-plane) and user data (U-plane), whereby the former is transmitted using macrocells with wider coverage, while the latter is sent through small cells that allow for higher speeds, thus increasing the overall speed and capacity of a network.

Source: "Electronic Components and Materials for 5G" (March 2021) compiled by Uzabase.

## Despite the global pandemic, global 5G network rollouts progressed during 2020



Source: Global Mobile Trends 2021, GSMA<sup>™</sup> Intelligence (as of 30 September 2020).

There are now 113 operators with 5G networks across 48 countries (Sep-2020). These operators collectively account for 40% of the global mobile subscriber base. Launches so far have been concentrated in China,

South Korea and the US.

38 Sessa Partners



3,500

3,000

2.500

0

2020

2021

2022

2023

Source: Ericsson Mobility Report \*Note: mobile PCs, tablets, routers

## Worldwide 5G Smartphone Subscriptions 2020 – 2026 (million) by Region

2,175





## Worldwide Mobile Subscriptions 2020 – 2026 (million, all devices) by Technology

Source: Ericsson Mobility Report June 2021. Note: includes smartphones, feature phones, mobile PCs, tablets, routers.

2024

2025

2026

According to the Ericsson Mobility Report June 2021, 5G subscriptions with a 5Gcapable device grew by 70 million during 1Q 2021, to reach around 290 million. Ericsson estimates 580 million total 5G device subscriptions by the end of this year. 5G subscription uptake is expected to be faster than that of 4G following its launch in 2009. Key factors include China's earlier engagement with 5G compared to 4G, as well as the timely availability of devices from several vendors. By the end of 2026, Ericsson forecasts 3.5 billion 5G subscriptions globally, accounting for around 40 percent of all mobile subscriptions at that time. The next 3 pages summarize the main implications for high growth in IoT applications, followed by Torex power management IC example product solutions for industrial IoT.

**Other 5G Device\*** Subscriptions (million)





India, Nepal, Bhutan

Central & East Europe

Middle East & Africa

3,352

167

367

2,756

113







The brief summaries on the right include excerpts combined from "The Impact of 5G on the United States Economy" by Accenture Strategy (February 2021) and "The 5G Economy in a Post-COVID-19 Era" by IHS Markit / OMDIA (November 2020).

The points below were highlighted in the Accenture analysis as transformative changes from 5G connectivity ramping up from 2021 – 2025.

## Benefits for

- MANUFACTURING
- 20 30% productivity gains
- 50% improvement in
- assembly efficiency20% increase in production
- assets life90% defect detection

#### **Benefits for AUTOMOTIVE**

- 80% reduction in accidents
- Big savings in repair costs
- 25% reduction in traffic

#### **Benefits for HEALTHCARE**

• 30% savings in transition to remote / home-based care

#### **Environment / Sustainability**

 Increased energy efficiency: 5G-enabled mIOT devices have longer battery and device useful lives

### The Promise of 5G: the Three Main Use Cases



Source: The 5G Economy in a Post-COVID-19 Era (November 2020), IHS Markit, OMDIA.

#### Enhanced Mobile Broadband (eMBB)

5G can deliver high bandwidth and speed to enable rich bi-directional transfer of high-definition video and high-volume data. High speed mobile broadband is foundational for enabling applications like augmented reality (AR) and virtual reality (VR) that require rich data transfer in both directions and will unlock entirely new ways of engaging with people and information in the age of computer vision (CV) and machine learning (ML). Two key facets of eMBB will drive adoption and value creation in the 5G economy. The first is extending cellular coverage into a broader range of structures, including office buildings, industrial parks, shopping malls, and large venues. The second is improved capacity to handle a significantly greater number of devices using high volumes of data, especially in localized areas. These improvements to the network will enable more-efficient data transmission, resulting in lower cost per bit for data transmission, which will be an important driver for increased use of broadband applications on mobile networks.

#### Massive Internet of Things (mIOT)

5G can provide simultaneous connectivity to potentially one million connections per square kilometer. This massively dense connectivity is essential to the effective implementation of advanced industrial Internet of things (IIoT) applications. One example of this is enabling large networks of sensors and machines to capture the rich data sets necessary to apply AI in smart power plants. 5G will build upon earlier investments in traditional machine-to-machine (M2M) and IoT applications to enable significant increases in economies of scale that drive adoption and utilization across all sectors. 5G's improved low-power requirements, ability to operate in licensed and unlicensed spectrum, and ability to provide deeper and more flexible coverage will drive significantly lower costs within MIoT settings. This will, in turn, enable the scale of MIoT and drive a much greater uptake of mobile technologies to address MIoT applications.

#### **Mission-Critical Services (MCS)**

For mission-critical applications such as automated vehicles or remote intensive care units (ICUs), the reliability and speed of the connection are crucial. 5G can carry network traffic with latencies as low as 1 ms, safely supporting use cases for which a fraction of an instant can make the difference between life and death. MCS represents a new market opportunity for mobile technology. This significant growth area for 5G will support applications that require high reliability, ultra-low latency connectivity with strong security and availability. This will allow wireless technology to provide an ultra-reliable connection that is indistinguishable from wireline to support applications such as autonomous vehicles and remote operation of complex automation equipment where failure is not an option.





Sessa Investment Research

★ IoT Analytics revised up its 2025 target for total global connected IoT devices from 21.5bn → 30.9bn, raising CAGR for all connected devices (IoT and Non-IoT) through 2025 to +12.8%.

Excerpts from "State of the IoT 2020: 12 billion IoT connections, surpassing non-IoT for the first time" (November 2020) by IoT Analytics, which is a leading provider of market insights for the Internet of Things (IoT), M2M, and Industry 4.0.





Smart Hon













Cyber-Physica Systems (CPS)

0

Software-Defined Networking (SDN)



nart City

ne (MZM)

Surveillance



## Global Active Device Connections (billion): IoT surpasses Non-IoT in 2020

Source: IoT Analytics – Cellular IoT and LPWA Connectivity Market Tracker 2010 – 2025 Note: Non-IoT includes all mobile phones, PCs, laptops and fixed line phones.

### IoT Analytics - Cellular IoT and LPWA Connectivity Market Update (November 2020)

Despite the ongoing Covid-19 pandemic, the market for the Internet of Things continues to grow. In 2020, for the first time, there are more IoT connections (e.g., connected cars, smart home devices, connected industrial equipment) than there are non-IoT connections (smartphones, laptops, and computers). Of the 21.7 billion active connected devices worldwide, 11.7 billion (or 54%) will be IoT device connections at the end of 2020. By 2025, it is expected that there will be more than 30 billion IoT connections, almost 4 IoT devices per person on average.

Compared to an analysis performed in mid-2018, IoT Analytics has now raised its forecast for the number of connected IoT devices in 2025 (from 21.5 billion to 30.9 billion). Several factors are driving the growth, most notably:

#### Cellular IoT – China

2011

2013

IoT has been booming in China at levels that seemed unimaginable a few years ago. While in 2015, for example, Chinese telecom companies accounted for roughly one quarter (27%) of all cellular IoT connections, this number has shot up to 75% in 2020 with China Telecom, China Unicom, and China Mobile leading the global cellular IoT connections market.

#### Personal and home devices

The pervasive use of personal IoT devices such as fitness wearables further accelerated in the last 2 years and is expected to continue to do so. The introduction and subsequent adoption of a new generation of ecosystem-enabled smart home devices such as the Amazon Echo led to faster adoption of connected home devices than previously assumed.

### **LPWA**

Counting a mere 10 million connections in 2015, the global market for low-power wide-area (LPWA) connectivity was quasi non-existent 5 years ago. LPWA enables IoT connections for remote batterypowered devices such as smart meters, containers in logistics, or critical infrastructure like fire hydrants in cities. In 2020 this market reached 423 million IoT connections and is expected to grow at a CAGR of 43% to reach 2.5 billion IoT connections by 2025. The picture in 2020 is that of a two-horse race. LoRa (and LoraWAN) technology, which is operating in the unlicensed spectrum and largely driven by the Lora Alliance, is in a head-to-head battle with NB-IoT, which is operating in the licensed spectrum and mostly driven by leading telecommunication firms around the world.







★ Smart Factories can connect multiple devices and systems and share data in real-time (IoT). Companies can now integrate multiple IT systems and collect, monitor, and track data across the factory floor as well as from the suppliers and customers across the value chain, achieving significant cost savings and productivity gains.

#### **Other IoT-related Trends:**

- Smart Logistics
- Smart Grids
- Smart Cities
- Smart Homes
- Smart Farming
- Smart Construction
- Remote Surveillance
- Edge Computing

Sensors used in smart factories have self-diagnosis and selfcalibration capabilities, which, for example within production systems, can predict maintenance requirements based on the vibration frequencies of the machines or changes in heat generated. This enables companies to benefit from extended machine life and decreased machine downtime.

### Industrial IoT and Industry 4.0 'Smart Factories'

Automated Factory (Industry 3.0) Smart Factory (Industry 4.0) Sensors have higher capabilities resulting in the Sensors deliver limited amounts of information Data ability to communicate more accurate and larger due to low processing power. Collection amounts of data in real time. · Does not possess the capabilities of self-adjusting & Sharing · Leverages onboard microprocessors to perform into real time changes. place/on-site diagnostics. · Data analysts to monitor and make decisions Form of based on data flowing through various systems. · Highly specialised machine operators. labour Job losses in some labour categories especially at the more low-end, low-skill levels. Advanced robotics used in smart factories possess · Automation of various tedious and mundane tasks higher capabilities of integrability and adaptability, carried out by humans. Automation autonomous decision-making, and self-optimising Unable to make decisions autonomously. Would capabilities. (Enabled through advanced machine require reprogramming. learning algorithms)

Source: "Smart Factories - The Imminent Transformation in Manufacturing" (February 2021) compiled by Uzabase.

### Smart Factory concept spans the entire production value chain



Source: Sierra Wireless, compiled by Uzabase.

Transition enabled by advancements in sensors, robotics, and data analytics

Loading and unloading machines		Transporting goods within the factory autonomously		Processing work pieces autonomously	
			0 0		
Mobile processing of large work pieces	S man	upporting ual processes	Autonomo quality inspec	us ction	Autonomous picking, packaging, and palletising
	0 0			7	

Source: BCG Global Advanced Robotics Survey, compiled by Uzabase.







## Torex Power Management Applications and Solutions for Industrial / IoT

The following is a brief summary of Torex product solutions targeting Industrial / IoT applications from the Company's website.

#### **Optical Transceiver**

Optical transceivers are commonly used for high-speed data communications, and they normally conform to industry standard form factors. This results in designers often needing to incorporate multiple power supply rails into a small predetermined physical space. Efficiency and power dissipation become very important and the latest optical transceiver chipsets demand supplies with low output noise performance and excellent transient response.

QSFP-DD is a module and cage/connector system similar to current QSFP (stands for four-lane Quad Small Form-factor Pluggable system), but with an additional row of contacts providing for an eight-lane electrical interface. It provides solutions up to 200 Gbps or 400 Gbps aggregate and uses PAM4 (4-level Pulse Amplitude Modulation) as well as NRZ modulation. Typically, QSFP-DD designs include an additional Digital Signal Processor (DSP) for PAM4, and they also require a negative voltage rail for the PAM4 EML (a laser source plus electro-absorptive modulator).



#### **Recommended Torex ICs**

- XCL303: Inductor built-in Negative Output Voltage DC/DC
- XCL219 / XCL223: Inductor built-in HiSAT-COT step-down DC/DC
- XCL102: Inductor built-in step-up DC/DC
- XC6127: High accurate voltage detector
- XC9266: 6A high speed transient response HiSAT-COT step-down DC/DC

### IoT Devices

IoT modules are increasingly used in industrial equipment, medical care and home automation. Normally in a small form factor, IoT modules monitor their surroundings and communicate the information over the internet. An IoT module will typically be battery powered and include various sensors, an MCU and a Radio for wireless communication. The use of small batteries is common, and the efficiency of the power supply is often very important for the designer.

### 1) Primary Battery

Many IoT devices use primary batteries which are non-rechargeable. The expected lifetime can still be long, so the power management solution chosen must have ultra-low power consumption to ensure efficient use of the battery to extend the operational lifetime. Torex offers may ultra-low power IC and in the example solution circuit we demonstrate a function that cuts the power consumption by disconnecting the battery during transportation and when the IoT module is not in use.

The block diagram (a) on the next page shows a typical application where the microprocessor (MCU) is directly connected to the battery. This architecture is often used for simple IoT devices, wearables and medical products. In recent years, the operating voltage range for MCU has also become wider and  $3.3 \text{ V} \sim 1.8 \text{ V}$  or lower is now common. As a result, many MCUs can now be connected directly to the battery without needing additional power supply IC. However, Radio IC and Sensors often still require a fixed 3.3 V supply and even if the operating voltage is wider, the supply Voltage needs to be carefully controlled and often the devices work better at higher Voltages, therefore a step-up DC/DC is sometimes necessary to boost the battery Voltage.





IoT Device – Primary Battery



#### **Recommended Torex ICs**

- XC6136: Ultra low consumption RESET
- XCL102 / XCL103: Inductor built-in step-up DC/DC, PWM (XCL102), PWM/PFM (XCL103)
- XC6233 (XC6215): Fast transient response / high PSRR voltage regulator
- XC6194: Push Button Intelligent Load SW

Normally, Radio IC and Sensors are not operated continuously, and the application firmware will be used to turn them ON and OFF as needed. For example, a Radio IC may only need to transmit and receive one time per day, possibly only for a few seconds, so it is more efficient to turn off the IC for the rest of the time to prolong battery life. During standby or sleep mode, when the Radio IC and Sensors are OFF and disabled, the operation of the power management IC used to supply them will also be turned OFF to conserve energy. This can be controlled easily using the devices CE or EN pin. Fixed frequency PWM mode ensures maximum efficiency at higher output loads and offers the lowest output ripple with easier noise management. Alternatively, PFM/PWM automatic switching can be used for improved efficiency during light loads. An inductor built-in type is also available, with better EMI suppression and smaller PCB area.

Low Drop Out (LDO) Voltage Regulators are often used to clean up a supply rail immediately after a DC/DC. The aim is to reduce noise and interference in the power supplies to the Radio and Sensors. For these Regulators, High Speed operation, with high levels of Power Supply Ripple Rejection (PSRR) is important together with Low Output Noise and fast transient response performance. With Torex 'Green Operation' (GO) the designer can combine these attributes with ultra-low quiescent current, because GO LDO will adapt their performance to the required output load. In some cases, the noise performance at higher frequencies can be important, and in these instances, a simple low speed, low quiescent current LDO may be a better choice.

A RESET IC or Voltage Supervisor, is often used to monitor the battery Voltage, if the Voltage drops below a predetermined level the RESET IC generates a signal for the MCU. These devices are always operating, so ultra-low quiescent current is an important consideration. If the MCU Voltage is the same as the monitored Voltage, a CMOS Output type can be used. The CMOS Output does not require an external pullup Resistor which helps to reduce unnecessary losses. When the MCU Voltage is different to the monitored Voltage an N-ch Output type should be used. An N-ch Output type will need an external pull-up Resistor and this will result in slightly higher current consumption across the resistor during reset. Some MCU have a built-in Under Voltage Lock Out (UVLO) or Analog to Digital Converters (ADC) which can be used to monitor the supply Voltage. However, it is often advantageous to have a separate IC to monitor critical Voltages independently of the MCU.

Block diagram (b) illustrates how a Push-Button Load Switch IC can be used to help maximize battery life, by disconnecting the battery from the rest of the circuit. The Schottky Barrier Diode (SBD) to the right of the SW pin in the diagram and the pull-up resistor to the VDD of the MCU are implemented so the push button can be shared with the MCU.



IoT Device – Li-ion Polymer



#### **Recommended Torex ICs**

- XC6190: Push Button reboot controller
- XC6136N (XC6135C): Ultra low consumption RESET
- XC9276 (XCL210): Ultra-Low Quiescent Current step-down DC/DC with selectable output voltage
- XC6803 (XC6804 / XC6808 / XC6806): Linear Li-ion Charger
- XC9281 / XC9282: Ultra small HiSAT-COT step-down DC/DC, PWM(XC9281), PWM/PFM(XC9282)

#### 2) Li-ion Polymer Battery

Some IoT devices are powered by rechargeable batteries and Li-ion and Li-Polymer are popular choices. These chemistries require dedicated charging IC and in our example solution circuit we illustrate the different options available from Torex. IoT devices powered by Li-ion or Li-Polymer batteries need a Charger IC and normally use step-down DC/DC or LDO Voltage Regulators to reduce the battery Voltage to a lower level required by the microprocessor (MCU) and peripheral IC. First, we will discuss the different types of Charger IC. When selecting a Charger IC we should consider the required Charge Voltage (CV) and Charge Current (CC). Often the CC is fixed externally using a Resistor (RISET) as shown in the block diagram. The CV is normally factory set by laser trimming.

With Li-ion or Li-Polymer batteries a PCM (battery Protection Circuit Module) is almost always required. These PCM can be integrated into the battery pack or placed on the PCB. The battery temperature can be monitored using a Thermistor (NTC) placed close to the battery on the PCB or inside the battery pack. For smaller batteries, temperature monitoring is not always required, and the Charge Status Output (CSO) function can be used to monitor the charge condition. The CSO pin has an N-ch Open Drain Output with external pull-up resistor. The output signal will be pulled 'HIGH' to march the level of MCU I/O Voltage. An LED can also be used to display the charge status and it is advisable to drive the LED through a current limiting resistor that is connected to VIN, to ensure the LED is not driven by the charge current supplied by the Charger IC. When the battery is used as part of a back-up circuit, a Charger IC with Current Path function may be desirable so that power can be supplied to the system while the battery is being charged.

The CV for Li-ion or Li-Polymer batteries is normally around 4.2V and the maximum input Voltage for the MCU is typically 3.8V or less, so a step-down DC/DC or Voltage Regulator is required to lower the battery Voltage for use within the system. Today's MCUs can operate in sleep or standby modes for long periods of time so high efficiency is required over a wide range of IOUT conditions from a few uA during sleep mode to 100mA or more when the MCU is operating fully. Using DC/DC with ultra-low quiescent current helps ensure high levels of efficiency when the MCU is in sleep mode and further savings can be realized by lowering the DC/DC output Voltage using a VSET function when the MCU enters sleep mode. Reducing the operating Voltage, even with the same quiescent current will significantly improve the overall system efficiency. When normal MCU operation is required, the DC/DC Voltage will need to be increased again, because many of the standard MCU functions require higher input Voltages to operate correctly. The MCU can switch between the different Voltage levels using the VSET pin. By varying the DC/DC Voltage in this way, we maximize the efficiency and help to prolong battery life.



#### **Industrial Sensors**



#### **Recommended Torex ICs**

- XCL225 / XCL226: Inductor built-in step-down DC/DC, PWM (XCL225), PWM/PFM (XCL226)
- XCL230 / XCL231: Inductor built-in step-down DC/DC, PWM (XCL230), PWM/PFM (XCL231)
- XC6233 / XC6223 (XC6215): Fast transient response / high PSRR voltage regulator
- XC6118 (XC6134): Low consumption voltage detector with separated sense pin and capacitor delay function
- XCL222: Inductor built-in step-down DC/DC HiSAT-COT PWM/PFM
- XC9258 (XC9282): Ultra-small HiSAT-COT step-down DC/DC, PWM/PFM, PWM/PFM(XC9282)

#### **Industrial Sensors**

Industrial sensors are typically powered by the host machine, so the input voltage is often 12V, 24V or more. They normally include various sensors, an MCU and a means of communication (either wired or wireless). Solutions with small physical size and high reliability are required and applications include building automation and security, monitoring of machinery, robotics etc. Although the number of applications is large, the typical circuit configuration is often similar and designers value efficiency, low output noise, low EMI and small size.

Industrial equipment will often be powered from a 12V or 24V primary power rail. Typical applications include, industrial sensors, factory automation and control equipment and robotics. Increasingly these application demand ever smaller, lower power solutions where efficiency and power dissipation become critically important. Block diagram (a) shows an example circuit where the primary DC/DC is directly powering the MCU. If the system spends periods of time in a low power mode, a DC/DC which switches automatically between PWM and PFM should be selected to maximize the efficiency under different load conditions. Alternatively, a DC/DC with fixed PWM mode can be used if a constant frequency is preferred or if the output load is always at a higher level. If the input Voltage is likely to drop to levels at or below the output Voltage, then a DC/DC with internal Pch switch, capable of operating with 100% duty cycle, should be used in order to maintain the output Voltage for as long as possible under adverse conditions.

In our example, the Voltage rail required to drive the sensor is close to the system Voltage so a LDO Voltage Regulator can be used efficiently. As a general rule, if Voltage Regulator is used, a high speed LDO Regulator, with high Power Supply Ripple Rejection (PSRR) and fast load transient response should be chosen to ensure a clean supply.

In a system where there are two distinct Voltage levels, we often refer to the initial power stage as the 'Primary' and the the next stage as the 'Secondary'. For example, the 'primary' stage in our diagram is the initial step-down from DC to 5.0V. The 'Secondary' stage includes all the subsequent rails powered from 5.0V, so in our example the two 3.3V rails are both 'Secondary'. The primary side is the same as Block diagram (a) above. However, for the secondary stage, it is possible to use lower Voltage DC/DC which are often smaller and more compact. Designers often prefer PWM/PFM auto switching DC/DC to maintain higher efficiencies at lower loads.





Small Li batteries rechargeable by LDO (nominal 2V to 3V)



#### **Recommended Torex ICs**

- XC6240 / XC6215: Low consumption small voltage regulator
- XC6140 / XC6136: Ultra-low consumption voltage detector

#### Small Li batteries rechargeable by LDO (nominal 2V to 3V)

A new generation of Li rechargeable, semi solid-state batteries which typically operate with a nominal voltage between 2V and 3V are now becoming common. These batteries can often be charged with a Constant Voltage using a simple LDO Voltage Regulator and the charging Voltage is normally set at a fixed level between 2.5V to 3.0V. Utilizing these batteries, a designer can realize a simple charging solution without the complexity normally associated with dedicated Li-ion charger IC. Our example solution circuit illustrates how this can be achieved. Applications include, powering small IoT devices and as a battery back up for industrial devices.

#### Benefits over traditional Li-Ion products:

- Ready for constant voltage charging by LDO. No need for a dedicated expensive CV / CC charging IC.
- Resistant to over-discharge and can be used with simple low voltage detection
- Because it is a battery, it can maintain a constant voltage around 2.2V to 2.3V for a long time. Energy can be used more easily and efficiently than a Supercap, which drops the voltage linearly.
- There are also products that can handle high temperatures such as 70° C and 105° C.
- Reflow / Hot laminating compatible products are also available.

A low consumption LDO Voltage Regulator is suitable to use with a large capacity secondary batteries as load. The battery is charged by a constant voltage provided by the LDO Voltage Regulator. The battery voltage rises to the LDO voltage regulator output voltage in a short period of time after the start of charging, and then the battery is gradually charged. It is not necessary to detect full charge, and it is generally not necessary to turn off the voltage regulator after full charge.

When the VIN is cut, the CE of the Voltage Regulator becomes 'Low' and the LDO turns off. The leakage current from the Li battery to the LDO becomes very small, this is called as the  $V_{OUT}$  sink current. Reverse current from the battery to  $V_{IN}$  is prevented by the SBD, and the pull-down resistor connected to the anode of the SBD switches the VE of the LDO to "L," and puts the voltage regulator into a standby state.

Ultra-low consumption voltage detectors can be used to monitor the battery voltage.

There are two main uses. When the battery voltage drops, the Voltage Detector stoppes the operation of MCU or next-stage power supply ICs. This prevents malfunctions of the operation of MCU when tbattery voltage drops. It is important to be able to suppress the quiescent current to a low level after detecting. Another way to reduce current consumption is to use the output of the voltage detector and Pch SW to cut off the power supply line.

If the battery voltage reaches or exceeds the release voltage of the voltage detector, a signal is output to start operation of the MCU or next-stage power supply IC. This makes it possible to prevent the system from repeatedly turning on and off due to internal impedance and inrush current when using a secondary battery with high internal impedance. A CMOS output type, which does not require a pull-up resistor, is suitable to reduce the quiescent current while operation is stopped.







PHEV





The EV market in Europe exceeded that of China for the first time in 2020, boosted by stimulus measures focused specifically on EVs (Germany did not provide any subsidies for conventional cars).

### EV / Connected Cars / ADAS (advanced driver-assistance systems)

The electrification of all categories of vehicles (passenger cars and light trucks, commercial trucks and buses) is entering a new phase of accelerated momentum, in addition to steady advances in technology, driven by: ① tightened emissions standards in place before the pandemic, ② enhanced EV incentives as part of stimulus measures to deal with economic stress caused by the pandemic, and ③ a generally heightened sense of urgency to combat the unrelenting deterioration from climate change (see the summary table on the following page).

According to the IEA's recently updated annual publication "Global EV Outlook 2021" (April 2021), despite the global slump in auto sales which declined -16% in 2020, new EV registrations of 3 million units increased +41% YoY, accounting for a 4.6% share of total auto sales (see table below), which lifted global EV stock to 10.2 million units (see graph on the next page). EV sales in Europe topped those of China for the first time as the world's largest EV market, with sales of BEVs doubling and sales of PHEVs tripling, driven by: ① stimulus measures specifically targeting uptake of EVs through purchase incentives and subsidy extensions, as well as cash-for-clunkers scrappage programs, and ② a more integrated approach to the transport sector by supporting charging infrastructure, EV public transport etc.

Out of the world's top 20 vehicle manufacturers, which represented around 90% of new car registrations in 2020, 18 have stated plans to widen their portfolio of models and to rapidly scale up the production of light-duty electric vehicles. Consumer spending on electric car purchases increased to USD 120 billion in 2020. In parallel, governments across the world spent USD 14 billion to support electric car sales, up 25% from 2019, mostly from stronger incentives in Europe. In the first-quarter of 2021, global electric car sales rose by around 140% compared to the same period in 2020, driven by sales in China of around 500k vehicles and in Europe of around 450k.

EV car sales	IEA	IEA	ΥοΥ	STEPS	STEPS	SDS	SDS
units, %	2019	2020	pct	2025	2030	2025	2030
Unit sales							
China BEV	834,197	931,291	11.6	3,363,610	6,599,817	5,742,530	8,380,270
China PHEV	226,106	228,291	1.0	1,184,041	2,337,131	2,019,110	2,321,434
Europe BEV	363,404	746,819	105.5	1,450,402	2,822,682	2,600,454	7,438,233
Europe PHEV	204,297	625,459	206.2	1,819,723	3,066,301	2,504,401	3,841,058
USA BEV	241,912	231,088	(4.5)	836,408	1,740,156	1,522,642	5,420,855
USA PHEV	84,732	64,311	(24.1)	386,353	759,813	619,786	1,745,347
Other BEV	103,354	98,826	(4.4)	1,463,842	3,208,023	2,073,834	7,448,366
Other PHEV	55,589	50,973	(8.3)	836,376	1,597,989	917,054	3,076,351
World BEV	1,542,867	2,008,024	30.1	7,114,262	14,370,678	11,939,460	28,687,724
World PHEV	570,724	969,034	69.8	4,226,493	7,761,233	6,060,351	10,984,190
World EV	2,113,591	2,977,058	40.9	11,340,755	22,131,911	17,999,811	39,671,914
Sales share							
China EV	4.79%	5.75%	_	20.09%	33.77%	35.01%	42.44%
Europe EV	3.21%	9.99%	—	19.23%	35.83%	32.87%	77.58%
USA EV	1.74%	2.04%	_	7.77%	15.69%	14.41%	49.58%
India EV	0.07%	0.06%	_	6.50%	10.88%	8.96%	29.24%
World EV	2.73%	4.61%	_	10.36%	17.31%	18.86%	36.02%

#### Prospects for Global EV Sales under Two Main Scenarios

Source: "Global EV Outlook 2021" (April 2021), International Energy Agency (IEA)

Note: Stated Policy Scenario (STEPS) - baseline with all existing announced initiatives

Sustainable Development Scenario (SDS) - meet climate goals of Paris Agreement







EV30@30 Campaign The EV30@30 Campaign was launched at the CEM (Clean Energy Ministerial) meeting in 2017 to spur the deployment of EVs. It sets a collective aspirational goal for EVs to reach 30% sales share by 2030 across all signatory countries. Fourteen countries endorsed the campaign: Canada, Chile, China, Finland, France, Germany, India, Japan, Mexico, Netherlands, Norway, Portugal, Sweden and United Kingdom.

### Tightened regulatory policies on automobiles and enhanced EV incentive programs

Country	Policy	Government Incentives and Benefits
USA	<ul> <li>10 states including California, Massachusetts, and New York introduced a ZEV programme, imposing a minimum ZEV requirement of 16% or more on manufacturers with annual sales of more than 4,500 vehicles.</li> </ul>	<ul> <li>Tax credit of up to USD 7,500 for EV purchase. (EVs and PHEVs equipped with batteries of 4 kWh or more, actual amount varies depending on the state)</li> </ul>
Germany	<ul> <li>Bundestag adopted a resolution to ban sales of all diesel and petrol engine cars by 2030 (not legally binding, but adopted with overall support).</li> </ul>	<ul> <li>Subsidies of up to EUR 6,000 (~USD 7,200) for BEVs and up to EUR 4,500 (~USD 5,400) for PHEVs, registered from June 2020 until end-2025.</li> <li>EVs registered from 2016 onwards are exempt from car tax for 10 years.</li> </ul>
France	<ul> <li>Government intends to ban all sales of petrol and diesel vehicles by 2040.</li> </ul>	<ul> <li>In June 2020, introduced subsidies of up to EUR 7,000 (~USD 8,400) for new BEVs and EUR 2,400 (~USD 2,400) for PHEVs with a cruising range of at least 50 km and a price of up to EUR 50,000 (~USD 60,000, duration extended until end-June 2021 in December 2020.</li> <li>An environmental incentive of EUR 1,000 (~USD 833) for the purchase of used EVs introduced from December 2020.</li> <li>Vehicles with CO2 emissions of 120g/km or more will be subject to a registration tax at the time of purchase.</li> </ul>
UK	<ul> <li>Government intends to ban all sales of passenger cars and vans with diesel and petrol engines from 2040.</li> </ul>	<ul> <li>While continuing to provide subsidies of GBP 3,000 (~USD 3,600) for purchases of BEVs, fully abolished subsidies for PHEVs in October 2018.</li> <li>Automobiles with CO2 emissions of 100 g/km or less are exempt from vehicle taxes. Additional taxes to be introduced gradually for automobiles with emissions exceeding 100 g/km.</li> </ul>
China	<ul> <li>Introduced "NEV regulations" that mandate that 10% (2019) of production/import volume be NEVs (EV, PHEV, FCV) for OEMs with annual production/import volume in China of 30,000 units or more.</li> </ul>	<ul> <li>Extended subsidies and vehicle purchase tax exemptions until 2022.</li> <li>Subsidies of CNY 16,200 to CNY 230,000 (~USD 2,500-3,500; varies depending on cruising range) for BEVs with a crusing range of 300 km or more and CNY 9,000 (~USD 1,300) for PHEVs. Additional subsidies from local governments prohibited from June 2019.</li> <li>Subsidies for vehicles with price up to CNY 300,000 (~USD 46,000), except for models with replaceable batteries.</li> <li>Limits on licence plates applied in major cities are relaxed for EVs</li> </ul>
Japan	<ul> <li>Government intends to mandate a fuel efficiency improvement of around 30% compared to FY2016 data (19.2 km/litre &gt; 25.4 km/litre) for new cars.</li> </ul>	<ul> <li>Subsidies of up to JPY 400,000 (~USD 3,600) for the purchase of BEVs and JPY 200,000 (~USD 1,800) for PHEVs. For vehicles registered after December 2020, the maximum subsidy amount increased to JPY 800,000 (~USD 7,200) for BEVs and JPY 400,000 (~USD 3,600) for PHEVs.</li> <li>Exempt from automobile acquisition tax.</li> <li>Incentives from some municipalities, including car tax credits for a certain period.</li> </ul>
	ΙΟν	HEV/PHEV BEV
	Front	Powertrain
	Transmission Inverter	Generator Fuel Tank
	Fuel Tank	

Source: "Electric Vehicles" (March 2021), compiled by Uzabase.





Despite the global slump in auto sales which declined -16% in 2020, new EV registrations of 3 million units increased +41% YoY, accounting for a 4.6% share of total auto sales, which lifted global EV stock to over 10 million units.



## Global EV Stock Outlook 2025 – 2030 (thousand cars) by Scenario



Source: "Global EV Outlook 2021" (April 2021), International Energy Agency (IEA)

As mentioned at the beginning of PART ONE, power management ICs (PMICs) are required in all microcontroller modules (MCUs), performing functions such as voltage regulation, undervoltage protection and voltage conversion. In addition to electrification of vehicles, related themes of connected cars and ADAS (advanced driver-assistance systems) offer promising demand for Automotive applications for power management ICs in sensor and camera modules. The next 2 pages summarize the main features of these applications, followed by Torex power management IC example product solutions for Automotive.

Entering a new era of accelerated uptake of EVs driven by policy initiatives and ambitious plans of leading automakers for new model launches









## Integration of internal vehicle data is accelerating the shift to 'Connected Cars'

Through bidirectional wireless communication, internal vehicle data, as well as external information on other vehicles on the road, road infrastructure, and maps can be exchanged between vehicles and applications in real time. Connected cars are not only connected to the internet, but also to various other devices with which they exchange information.

## ITS (intelligent transport systems) services related to Connected Cars

Improving safety and solving Connected Cars represent one social problems such as traffic congestion of the four major areas of development shaping the Safety Field **Agency Field** future of the global automotive sector, which are In-Car Data Out-of-Car Data collectively known as "CASE" (Connected, Autonomous, Shared, and Electric). Driving Assistance/ **Autonomous Driving Systems**  Car speed, acceleration • Steering angle • Traffic lights, road signs **Optimal Traffic Control**, **Emergency Information**/ Dynamic Maps/I2V **Road Assistance in**  Map information Event of Accidents **Disaster Notification**  Location information Airbag deployment Systems Full LCD display rear view Traffic congestion and · Sensor, voice Natural disaster Utilising accident information information mirror-type drive recorder (DR) information Utilising vehicle/ external road Vehicle Management, information information Telematics Insurance Sharing/MaaS Vehicle status Virtual Passengers Information (fuel level (VR) Distribution battery charge) Nearby shops, restaurants Maintenance Sightseeing information history • Music, video, games Car Life Support Field **Infotainment Field** Source: MAXWIN Improving quality of life **Connected Cars: Map of Connections** Telematics refers to systems that connect cars with the Road Traffic Information Centre **GNSS** Satellite external environment Light duration Traffic data. Location Map data update 4 h 6 ت, Traffic data 0 Accident auto-report Presence of lu vehicle Relative position/ speed check [V2V] Data on people and vehicles in 🌖 Distance from each other [V2P] blind spots [V2I]

Source: "Connected Cars" (March 2021), compiled by Uzabase.



Sessa Investment Research

ADAS systems allow for the replacement of human perception, judgment, and operation through a combination of multiple technologies. Perception can be broadly divided into location awareness and external environment awareness. The key to autonomous driving, however, is to combine data obtained from various sensors to allow for accurate awareness of the external environment and to make appropriate driving decisions based on this databased awareness.

### **ADAS Driving Levels**

		Level	Overview	Example	
Î		0	Human driver carries out all driving operations	-	
Driver	Driving Ass	1	System provides support for either steering or acceleration/deceleration operations	Automatic braking system Adaptive cruise control (ACC) Lane keep assist	Current
↓ ↓	istance	2	System provides support for both steering and acceleration/deceleration operations	Tesla Auto Pilot (2015) Nissan ProPILOT (2016	
	Autonomo	3	System carries out all driving operations in specific environments, such as highways, but requests that a human driver immediately intervene when it comes into difficulty	Audi A8 (2018) Honda Legend (planned launch in 2020)	Legislatio
OO System	us Drivi		System carries out all driving operations in specific environments, such as highways	Waymo One	n Requir
	gu	5	System carries out all driving operations in all environments	-	ed

## Main sensors used to perceive the external environment by ADAS systems

	Perception		Judgement	Operation
Location Information	Location Awareness (Satellite Positioning)	External Environment Awareness (Sensors)	<ul> <li>Machine Learning</li> <li>Semiconductors</li> </ul>	<ul> <li>Acceleration/ Deceleration,</li> </ul>
<ul> <li>2D Maps (lanes, signs, etc.)</li> <li>3D Maps</li> </ul>	<ul> <li>GPS, GNSS</li> <li>Quasi-Zenith Satellite System (QZSS)</li> </ul>	<ul> <li>Cameras, LiDARs, millimetre-wave radars, ultrasonic radars, etc.</li> </ul>		Braking • Steering
۲	$\left(\left(\left(\bullet\right)\right)\right)$		° <b>≟≣</b> ⊂	**

	Camera	Millimetre Wave Radar	LiDAR	Ultrasonic Sonar
Close Range Detection (>1m)	Δ	Δ	Δ	Ø
Detection at 100m	0	O	Ø	×
Distance Accuracy	0	0	Ø	$\bigtriangleup$
White Road Markings	Ø	×	Δ	×
Traffic Lights/Signs	0	×	×	×
Rainy/Snowy Conditions	Δ	0	0	0
Foggy Conditions	Δ	O	0	0
Nighttime	0	0	0	O

 $\bigcirc$ : Very Good  $\bigcirc$ : Good  $\triangle$ : Usable  $\times$ : Unusable

Source: "Autonomous Driving" (December 2020), compiled by Uzabase.



#### ★ There is promising demand for power management ICs in sensor and camera modules



#### ADAS Level 5 is full autonomous driving







Compact units directly connected to 12V battery

ර Compact units connected to 8V secondarly rail

Automotive camera modules

### **Torex Power Management Applications and Solutions for Automotive**

The following is a brief summary of Torex product solutions targeting Automotive applications from the Company's website. Torex's automotive products (XD series) comply with the guidelines of AEC-Q100. This standard, which was established by the AEC (Automotive Electronics Council), prescribes reliability tests and quality tests for integrated circuits. Stricter requirements are adopted than for consumer electronics to ensure high quality in automotive products.

#### Compact units directly connected to 12V battery

Examples of various types of compact units, sensors, and modules to be directly connected to 12V battery. Requirements for power supplies are becoming more severe particularly for compact sizes, low noise, and low power consumption, due to an increase in the number of various sensors, controllers, modules, and units controlled by ECU and used in internal automobile components, as well as advancements in their functionality.

Primary step-down DC/DC generally have a structure where the voltage is decreased to the common voltage at the first stage, and then decreased further at the second stage to the individual required voltages to be supplied. These are referred to as the primary power supply and secondary power supply respectively. For primary DC/DC, use a switching frequency of 2MHz or greater in consideration for EMI. If a light load condition will be experienced for a long time, and a decrease in frequency during that time is allowed, select the PWM/PFM automatic switching type. If it is desired to keep the operating frequency constant regardless of the load condition, select the PWM fixed type. Also, starting from conditions such as cold cranks or idling stops, or elements such as long harnesses, will cause the power supply line voltage to decrease significantly, so the Pch SW type, which supports a duty ratio of 100% and can easily maintain the output voltage even when there is a drop in input voltage, is suitable in such cases.



#### **Recommended Torex ICs**

• XDL605 / XDL606 (XD9267 / XD9268): Inductor built-in step-down DC/DC, PWM (XDL605), PWM/PFM (XDL606)

• XD6132: Separated sense (VSEN) pin and capacitor delay type low-power voltage detector

• XDL601 / XDL602 (XD9260 / XD9261): Inductor built-in HiSAT-COT step-down DC/DC, PWM (XDL601), PWM/PFM (XDL602)

• XD6506: Low consumption, low noise voltage regulator

It is recommended to use a compact, high-speed response, low-noise DC/DC to the secondary power supply for ECU. Although it is common to use a value of 2MHz or greater for the DC/DC switching frequency, since it is not directly connected to the outside using a harness as with a primary DC/DC, a relatively lower frequency may be used in some cases for greater efficiency. The XD9260 and XD9261 include both 3.0MHz and 1.2MHz types for this reason. Due to their low noise, the same DC/DCs used in ECUs are suitable for sensor power supplies as well.

Voltage detector with a separated sense (VSEN) pin is used for monitoring the input voltage on the primary side. Monitoring the input Voltage to helps to ensure stable operation and is useful for power sequencing (when implementing start-up and shut-down sequences). The VSEN pin uses divider resistors which are connected to the primary side input voltage supply. The divider circuit allows the Voltage Detector to monitor voltages that exceed the absolute maximum voltage range of the IC. The voltage detector signal is needed when the MCU is operational, so the voltage detector is powered from the primary output. And the RESETB output is connected to the MCU's I / O and is monitored by the MCU.





Compact units connected to 8V secondary rail



#### **Recommended Torex ICs**

- XDL603 / XDL604: Inductor built-in step-downDC/DC, PWM (XDL603), PWM/PFM (XDL604)
  - XD6506: Low consumption, low noise voltage regulator

#### Compact units connected to 8V secondary rail

Examples of various types of sensors and modules operated by a power supply of roughly 8V, generated from 12V battery through a primary power supply. Simple, ultra-compact power supplies with low noise are introduced. There are many cases where various sensors and modules connected to main units for infotainment are supplied by a power supply of roughly 8V created by a primary DC/DC within those main units.

For primary step-down DC/DC, the voltage is already stabilized to a constant value of 8V and then input, so it can be directly decreased to the ECU voltage of 3.3V. Since there are some cases where the harness will be longer, in such cases use a DC/DC with a switching frequency of 2MHz or greater in consideration for EMI. If a light load condition will be experienced for a long time, and a decrease in frequency during that time is allowed, select the PWM/PFM automatic switching type. If it is desired to keep the operating frequency constant regardless of the load condition, select the PWM fixed type. Also, during cold cranks, due to a decrease of this 8V and fluctuations caused by long harnesses, the Pch SW type, which supports a duty ratio of 100% and can easily maintain the output voltage even when there is a drop in input voltage, is suitable in such cases.

The PG (Power Good) pin of the primary DC/DC can be used as the RESET output for monitoring the power supply voltage of the ECU. By signaling that the voltage has risen up sufficiently before starting operation of the ECU, and also signaling when there is a drop in voltage, ECU malfunctions can be prevented.

Obtaining power supplies for sensors in this way from the power rail for the ECU using LDOs is a simple and efficient method of controlling heat generation characteristics. Since low noise and ripple are important, LDOs which have low power and low noise are ideal. The sensor is only turned ON when necessary, so the CE signal is controlled by the ECU.

## Applications of automotive products

From car infotainment to general automotive accessories, we will release products for a wide range of applications.

#### Examples of applications of our products

- DC/AC Inverter
- GPS Module
- Car Navigation System
  - Remote touch
- Back monitor camera
- Power sliding door
- Meter

Sub monitor

 Power windows Head-up display

• ETC/DSRC

Air Conditioner

Keyless Entry

- Monitor for rear seat
- Car-mounted camera





## is an R&D facility for highfunction, high-performance

The Kansai Technology Center

analog power management ICs for automobiles. Previously the product design, massproduction technology and quality assurance functions were decentralized in Sapporo and Okayama, but in May 2016 they were consolidated in Osaka. This allows Torex to achieve both better quality and faster start of mass production.



Automotive camera modules



#### **Recommended Torex ICs**

• XDL605 / XDL606 (XD9267 / XD9268): Inductor built-in step-down DC/DC, PWM (XDL605), PWM/PFM (XDL606)

• XD6132: Separated sense (VSEN) pin and capacitor delay type low-power voltage detector

• XDL601 / XDL602 (XD9260 / XD9261): Inductor built-in HiSAT-COT step-down DC/DC, PWM (XDL601), PWM/PFM (XDL602)

• XD6130 / XD6131: Voltage detector with watchdog function

#### Automotive camera modules

There are two possible cases for automotive camera modules: directly connected to 12V battery or supplied by a primary power supply output of roughly 8V. Examples of solutions suitable for automotive camera modules, whose miniaturization is continuing to advance, are presented. A large number of camera modules are now used in automobiles, with requirements for their power supplies to have even smaller sizes, higher efficiency, lower noise, and lower power consumption.

Primary step-down DC/DC generally have a structure where the voltage is decreased to the common voltage at the first stage, and then decreased further at the second stage to the individual required voltages to be supplied. These are referred to as the primary power supply and secondary power supply respectively. For primary DC/DC, use a switching frequency of 2MHz or greater in consideration for EMI. If a light load condition will be experienced for a long time, and a decrease in frequency during that time is allowed, select the PWM/PFM automatic switching type. If it is desired to keep the operating frequency constant regardless of the load condition, select the PWM fixed type. Also, starting from conditions such as cold cranks or idling stops, or elements such as long harnesses, will cause the power supply line voltage to decrease significantly, so the Pch SW type, which supports a duty ratio of 100% and can easily maintain the output voltage even when there is a drop in input voltage, is suitable in such cases.

Step-down DC/DC for ISP and CMOS sensor with compact sizes, high-speed response, and low noise are recommended for each secondary power supply rail. Although it is common to use a value of 2MHz or greater for the DC/DC switching frequency, since it is not directly connected to the outside using a harness as with a primary DC/DC, a relatively lower frequency may be used in some cases for greater efficiency. The XD9260 and XD9261 include both 3.0MHz and 1.2MHz types for this reason.

Voltage detector with a separated sense (VSEN) pin is used for monitoring the input voltage on the primary side. Monitoring the input Voltage to helps to ensure stable operation and is useful for power sequencing (when implementing start-up and shut-down sequences). The VSEN pin uses divider resistors which are connected to the primary side input Voltage supply. The divider circuit allows the Voltage Detector to monitor voltages that exceed the absolute maximum voltage range of the IC. The VIN supply for the Voltage Detector is connected to the output side of the primary DC/DC (5.0V in our example).

One RESET IC with the watchdog function can monitor both the ISP power supply voltage and normal operation. The voltage monitoring function signals when the secondary DC/DC output voltage has risen up sufficiently, begins operation of the ISP, and also signals when the voltage drops to prevent malfunction of the ISP. After ISP start-up, if a pulse from the ISP reaches the WD pin at regular interval, the operation is judged to be normal. If that signal is not received, the ISP is judged to be out of control, and it is restarted by applying a RESET signal.







**Next-gen Power Devices** 

**MOSFET** (Metal Oxide Semiconductor Field Effect Transistor) is a class of voltagedriven devices that do not require the large input drive currents of bipolar devices.

IGBT (Insulated Gate Bipolar Transistor) combines the characteristics of a power MOS transistor and a thyristor. IGBT devices are usually found in high-voltage circuits (above 300V).



Source: ROHM Semiconductor

#### **Introduction to Power Devices**

Power semiconductors are used in electronic devices to reduce power loss from a circuit, and thus reduce the consumption of electricity. One representative device in which a power semiconductor is included is an inverter. Demand for power semiconductors has expanded mainly in the markets for in-vehicle components, electrical/electronic equipment, machine tools, and industrial motor drives for industrial robots. Electric vehicles (EVs) are equipped with an electric motor which requires an inverter to operate, and power semiconductors are an essential component for motor inverters.



Source: excerpt from "Power Device Industry Overview – Japan" (June 2020) compiled by Uzabase.

Low- and medium-voltage MOSFETs are used to provide power switching functions in portable electronic devices, PC power supply units etc. High-voltage MOSFETs are used in LCD TV driver units. IGBTs are used in the power switching elements of inverter circuits, which convert direct current into alternating current. They have a variety of applications, from amplifying voltage to controlling motive power. These chips are generally used in higher voltage power ranges than MOSFETs. Applications include home appliances, DSCs, trains, machine tools and electric vehicles (EVs).

Functions and Capabilities of Power Semiconductors					
Type of Power Semiconductor	IC Functions	Converter	Converter Functions		
Diode	Rectification	Rectifier	Rectification		
Thyristor	Automatic power-on	PAM Inverter	AC output		
Transistor, GTO thyristor	Automatic power-off	PWM Inverter	Precision, efficiency, reduced size		
MOSFET IGBT	High-speed switching	High-frequency PWM inverter	Precision, efficiency, miniaturization		
RB-IGBT	Low-loss and small bi-directional switching	Matrix converter	Precision, efficiency, miniaturization of bidirectional AC output		

Source: Fuji Electric, excerpt from "Power Device Industry Overview – Japan" (June 2020) compiled by Uzabase.



Next-gen SiC and GaN compound semiconductors are taking the place of Si which is reaching its theoretical limits to lower ON resistance (to lower power loss)

Until recently, performance of power devices was enhanced through structural improvements, such as deep-trench Super-Junction MOSFETs. However, these improvements are said to be reaching theoretical limits due to the physical properties of the material used to make the devices (silicon and polysilicon). New materials silicon carbide (SiC) and gallium nitride (GaN) offer lower ON resistance properties and can reduce power loss significantly. Since they can handle high voltages, they are they are suited for use in high-voltage applications such as power generation, trains, and industrial equipment, and are particularly well suited for use in vehicle engines, which require high-voltage power supplies of around 1 kilovolt (kV). The issue has been the high cost of producing bulk single crystals from compound materials like SiC, but technological advances are making mass production feasible.



#### Key Advantages of SiC and GaN Power Semiconductor Devices

Source: excerpt from "Power Device Industry Overview – Japan" (June 2020) compiled by Uzabase.

#### Omdia forecasts SiC and GaN power device market to reach \$1 billion in 2021

According to Omdia which specializes in telecommunications, media and technology market research, GaN is a wide-bandgap material offering similar performance benefits as SiC, but with a higher cost-reduction potential because GaN power devices can be grown on either silicon or sapphire substrates, which are less expensive than SiC. The emerging market for silicon carbide (SiC) and gallium nitride (GaN) power semiconductors is forecast to pass \$1 billion in 2021, driven by demand from hybrid and electric vehicles, power supplies, and photovoltaic (PV) inverters.

The two graphs on the top of the next page show that Omdia forecasts this market to grow at **CAGR of +22.3% to \$5 billion by 2029**, with SiC power modules and discrete SiC power devices leading growth by technology, and by application, hybrid and electric vehicles and power supplies.

Another point highlighted by Omdia is that this emerging market for silicon carbide (SiC) and gallium nitride (GaN) power semiconductors is rapidly evolving from a startup-dominated business to one led by large-established power semiconductor manufacturers.



## SiC and GaN Power Semiconductors by Technology (\$ million)





## SiC and GaN Power Semiconductors by Application (\$ million)

Source: excerpt from "GaN & SiC power semiconductor markets set to pass \$1 billion mark in 2021" (July 2020), by Omdia.

While Japan has ceded dominance in certain areas of semiconductors, leading manufacturers like RENESAS Electronics (6723 TSE1), ROHM Semiconductor (6963 TSE1), Mitsubishi Electric (6503 TSE1), DENSO Corporation (6902 TSE1) etc. are global leaders in next-generation power devices.

Here its is worth noting that established US player Littelfuse acquired SiC start-up Monolith Semiconductor, and then bought established company IXYS Corporation in 2018. As noted earlier in PART TWO, Phenitec's largest customer IXYS Corporation (owned by Littelfuse NASDAQ LFUS) accounted for 10.8% of total FY3/21 Group sales.





Schedule for advancing development of next-generation SiC power devices

# Development of SiC devices on Kagoshima's 6-inch line Developing price-competitive SiC SBD (Schottky Barrier Diode) SiC SBD Sample shipments started

A CONTRACT

Participating as an Associate Member of Tsukuba Power Electronics Constellations (TPEC) promoted by the National Institute of Advanced Industrial Science and Technology (AIST) toward further cost reduction and R&D of SiC MOSFETs



Preparing for mass production Uses high-concentration substrate ↓ Process simplification Chip size shrink ↓ ✓ Low cost ✓ High quality SiC devices produced in-house

In the future, we will make capital investment according to the progress of development and mass production of SiC-SBD and SiC-FET. Source: excerpt from 4Q FY3/21 IR results briefing materials, May 24, 2021.





NCT 4-inch beta-gallium oxide β-Ga₂O₃ epitaxial wafer



Source: Novel Crystal Technology June 16, 2021 press release.

Torex capital tie-up partner Novel Crystal Technology achieves world's first mass production of 100mm (4-inch) beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) epitaxial wafers, making it possible to mass produce next-generation power devices (June 16, 2021)

Previously Novel Crystal Technology had announced in April 2019 that it succeeded in developing high-quality 50mm (2-inch) beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) epitaxial wafers, and it has been manufacturing them and selling them since then, but they are limited to use for R&D since mass production is not economically viable with 2-inch wafers. Compared with silicon carbide (SiC) and gallium nitride (GaN), beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) has large band gap energy of 4.5eV (electron volts) which translates to lower loss of power, making it ideal for applications such as electric vehicles (EV) and other industrial equipment. In addition, beta-gallium oxide bulk single crystals are grown using the melt growth method, which is 100 times faster than the vapor growth method used for SiC and GaN. Finally, since beta-gallium oxide has a hardness similar to silicon, it can be processed (cutting and polishing) using existing equipment for silicon wafers (reducing the capex burden for customers).

NCT succeeded in demonstrating beta-gallium oxide low-loss Schottky barrier diodes (SBD) with a trench structure in September 2017, and it will continue to build mass production technology for trench-type SBDs on the 100mm line. The company plans to supply 150mm (6-inch) beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) epitaxial wafers in 2023.

Torex announced a capital tie-up with Novel Crystal Technology on June 30, 2020, as Group subsidiary Phenitec is also working on developing next-generation power devices, and the market for ultra low-loss and low-cost power devices is expected to grow rapidly over the next decade. NCT's  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> is summarized on the next 2 pages.



60 Sessa Partners



#### **Business Description**

 Manufacture and sale of substrates with gallium oxide epitaxial film

• Manufacture and sale of single crystals and their applied products • Manufacture and sale of semiconductors and their

applied products

### Head Office

2-3-1 Hirosedai, Sayama City, Saitama (41 employees 2020.6)

President and CEO Akito Kuramata



Large band gap energy of 4.5eV (electron volts) means lower loss of power. Silicon is reaching its theoretical limit to lower ON resistance.



#### **NCT Shareholders:**

- Tamura Corp. (6768): 38%
- Individual investors: 36%
- Corporate investors: 26%

## **Corporate investors:**

- AGC (5201) • TDK (6762)
- Iwatani Venture Capital
- Satori Electric (7420)
- Shindengen Electric (6844)
- JX Nippon Mining & Metals
- Sojitz Machinery Corp.
- Torex Semiconductor (6616)
- Yaskawa Electric (6506)

Source: NEDO Project Review: Practical Development of Amperegrade Gallium Oxide Power Device <July 2018 – May 2020>

Summary of Novel Crystal Technology's next-generation power device material betagallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) epitaxial wafers and bulk single crystal growth technology Established in June 2015, Novel Crystal Technology Inc. is a carve-out venture of Tamura Corporation (6768 TSE1) and a technology transfer venture of NICT (National Institute of Information and Communications Technology), and along with the Tokyo University of Agriculture and Technology, it is advancing research on beta-gallium oxide, a promising next generation power device material, aiming to IPO in 2023.

Novel Crystal Technology Inc. is developing and manufacturing  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> substrates and epitaxial wafers. It also leads the world in bulk single crystal growth technology, epitaxial film-forming techniques and power device fabrication technology. With the growing call for a carbon-free society, renewable energy development and efficient power usage are expected to build momentum.  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> power devices have promising applications in electric vehicles, robots and a host of other industrial equipment, contributing to sustainable society.

## Features of β-Ga<sub>2</sub>O<sub>3</sub>: Promising Next-Generation Power Device Material - Comparison with other wide band-gap semiconductor materials







High growth rate due to melt growth (30 mm/h)

The closer to the bottom-right corner, the greater the material's ability to realize a device that both saves energy and has a high breakdown voltage. Silicon is the material currently used for power devices, yet it is reaching its performance limits. Silicon carbide (SiC) and gallium nitride (GaN) have wider band gaps and greater theoretical values than Si, yet beta gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) surpasses them both.

## $\star$ Cost / performance advantages of beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>)

## Difference in bulk crystal growth speed

With SiC and GaN, bulk single crystals are generally grown using the vapor growth method. However, the issues with this method are that only several hundred micrometers can be grown per hour, and high-quality crystals are difficult to produce. Meanwhile, beta gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) is grown using the melt growth method. With a growth rate of several dozen millimeters per hour, this method is approximately 100 times faster than the vapor growth method, enabling the production of high-quality bulk single crystals. The speed at which the bulk single crystals can be grown translates to noticeably lower crystal growth costs.







Source: NCT company website



## **2** Easy to process (cutting, polishing)

Because both SiC and GaN are extremely hard materials, the process of cutting out substrates from bulk single crystals and polishing them is time-consuming and labor intensive. Meanwhile,  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> has a hardness similar to silicon. This means it can be processed easily in the same facilities as silicon.

## **3** Development of large-diameter substrates has progressed rapidly

With SiC, it took roughly 15 years to develop a 6-inch substrate (1997 – 2012). With  $\beta$ -Ga<sub>2</sub>O<sub>3</sub>, the same was achieved in just 5 years (2012 – 2017).

## Summary of beta-gallium oxide ( $\beta$ -Ga<sub>2</sub>O<sub>3</sub>) characteristics:

- 1) Energy saving / high breakdown voltage (ultra low-loss)
- 2) Bulk single crystals can be grown rapidly (100x faster than the vapor method)
- 3) The material is easy to process on existing equipment for silicon wafers
- 4) Large diameter substrates were achieved in a short time period

# NEDO Project: Practical Development of Ampere-grade Gallium Oxide Power Device <July 2018 – May 2020>

- NCT (project co-leader): killer defect evaluation, epiwafer, polishing, diode proving
- Fujikoshi Machinery Corp. (project co-leader): Vertical Bridgman (VB) technique for growing beta gallium oxide crystals
- Saga University: killer defect evaluation
- Shinshu University: VB technique for growing beta gallium oxide crystals
- AGC (5201): polishing
- TDK (6762): killer defect evaluation, diode proving
- Cooperating companies: Tamura Corporation (6768), Nippon Sanso Holdings (4091)



## Next-generation Power Device Market Forecast



Note: Forecast market size is calculated based on the current status and future outlook of the 2020 edition of Next-generation Power Device & Power Electronics-related Equipment Market (by Fuji Keizai Co., Ltd.)

Source: excerpt from NEDO Project Review: Practical Development of Ampere-grade Gallium Oxide Power Device < July 2018 – May 2020>



Sessa Investment Research



PART FIVE: Share Price, Valuations and Shareholder Rebates

Performance and Valuations: SESSA Smart Charts

- Despite the sharp rise in the share price, valuations are not extended, and the P/E is trading below its historical average.
- ✓ Ultimately this is the nature of powerful cyclical recoveries, and current-term forecasts cannot capture the true upside potential, in our view.
- ✓ The three key mediumterm growth drivers examined in detail in PART FOUR point to a robust growth period as they converge during the current 5-year MTP.



Analyst's view



Source: compiled by Sessa Partners from SPEEDA historical earnings and price data. Valuations calculated based on CE.



3-Year Weekly Relative Performance



Source: compiled by Sessa Partners from SPEEDA historical price data.

The lower left table shows that **both Phenitec Chairman Fujisaka and Torex President** Shibamiya are in the top 10 shareholders, whose interests are aligned with all shareholders, an attractive point that cannot be understated in our view.

The company's stated dividend policy is highlighted in the graph below: consolidated dividend payout ratio of at least 20%, aiming for DOE of 3.0%. Like many Japanese companies, a common point of frustration among foreign shareholders is policy which emphasizes 'stable' dividends. It is also true that Torex has a large net cash position, and given that its business is highly cash generative, the unrelenting increase in shareholders' equity will make the DOE target of 3.0% increasingly difficult to achieve. HOWEVER, it is also true that management did not hesitate to approve a 5.2% share buyback, and in that respect, is not the same as many Japanese companies, nor is two top managers among the top 10 shareholders. "Actions speak louder than words."

# TOREX SEMICONDUCTOR Major Shareholders (2021/03/31)

(2021)	(05/51)	
Rank	Shareholder	(%)
1	The Master Trust Bank of Japan, Ltd. (Trust Acct)	9.01%
2	Custody Bank of Japan, Ltd. (Trust Acct)	7.02%
3	THE BANK OF NEW YORK 133652	6.93%
4	Tomoyuki Fujisaka (Phenitec Chairman)	4.60%
5	The Chugoku Bank, Limited	4.28%
6	ARS Co., Ltd.	4.10%
7	Kibi Kogyo Co., Ltd.	3.61%
8	Takanori Ozaki	2.91%
9	Koji Shibamiya (Torex President)	2.67%
10	Kimiko Ozaki	1.86%
Top 10	-	46.99%
Source: I	FY3/21 YUHO financial statements.	









reflecting strong underlying earnings momentum, in our view.

Source: compiled by Sessa Partners from SPEEDA price data.

## i cer und ney

Peer and Key N. America Client 3-Year Weekly Relative Performance



Source: compiled by Sessa Partners from Yahoo Finance US historical price data.



★ Timing of next-generation power device business actually turning profitable (into the black) likely holds one of the keys for the future direction of the share price. In the meantime, since valuations have not yet become overheated, we expect there is high potential the share price will settle into and establish a new trading range,





TOREX SEMICONDUCTOR





# Consolidated Balance Sheets 1

		I nousands of yer
	Previous FY-end	Current FY-end
	As of March 31, 2020	As of March 31, 2021
sets		
nd deposits	9,281,215	11,737,170
and accounts receivable - trade	4,020,517	4,629,998
andise and finished goods	2,042,628	1,734,438
in process	1,900,144	2,448,495
naterials and supplies	1,064,040	1,287,325
	540,103	590,124
ance for doubtful accounts	(2,983)	(5,948)
current assets	18,845,666	22,421,604
nt assets		
rty, plant and equipment		
uildings and structures, net	2,525,605	2,429,076
achinery, equipment and vehicles, net	1,228,729	1,259,066
ools, furniture and fixtures, net	494,403	375,861
nd	1,147,187	1,247,258
ased assets, net	155,134	148,070
onstruction in progress	653,463	506,612
tal property, plant and equipment	6,204,524	5,965,946
ible assets		
ftware	170,524	870,668
her	630,949	48,683
otal intangible assets	801,474	919,351
ments and other assets		
vestment securities	913,366	966,440
etirement benefit asset	-	321,973
eferred tax assets	693,158	535,578
her	414,452	407,657
lowance for doubtful accounts	(25,680)	(26,422)
tal investments and other assets	1,995,296	2,205,227
ion-current assets	9,001,295	9,090,525
ts	27,846,962	31,512,129





# Consolidated Balance Sheets (2)

		Thousands of yen
	Previous FY-end	Current FY-end
	As of March 31, 2020	As of March 31, 2021
Liabilities		
Current Liabilities		
Notes and accounts payable - trade	1,065,830	1,344,974
Short-term borrowings	2,901,627	2,901,661
Current portion of long-term borrowings	605,036	1,030,000
Lease obligations	56,114	47,560
Accounts payable - other	1,503,574	1,052,957
Income taxes payable	51,380	203,234
Provision for bonuses	355,975	424,979
Other	403,059	673,724
Total current liabilities	6,942,598	7,679,092
Non-current Liabilities		
Long-term borrowings	1,142,500	3,362,500
Lease obligations	43,283	45,248
Long-term accounts payable - other	202,648	68,476
Retirement benefit liability	656,153	344,767
Provision for share awards	53,546	49,109
Asset retirement obligations	81,965	83,336
Deferred tax liabilities	41,455	60,769
Other	10,908	28,906
Total non-current liabilities	2,232,461	4,043,114
Total liabilities	9,175,060	11,722,207
Net assets		
Shareholders' equity		
Share capital	2,967,934	2,967,934
Capital surplus	8,297,198	8,299,941
Retained earnings	8,576,276	9,115,933
Treasury shares	(788,207)	(749,981)
Total shareholders' equity	19,053,202	19,633,828
Accumulated other comprehensive income		
Valuation difference on available-for-sale securities	(145,538)	(146,619)
Foreign currency translation adjustment	15,011	113,934
Remeasurements of defined benefit plans	(250,774)	188,778
Total accumulated other comprehensive income	(381,300)	156,093
Total net assets	18,671,901	19,789,922
Total liabilities and net assets	27,846,962	31,512,129



## **Consolidated Statements of Income**

	Thousands of yen		
	For the FY ended	For the FY ended	
	March 31, 2020	March 31, 2021	
Net sales	21,500,955	23,712,981	
Cost of sales	16,049,185	17,753,827	
Gross profit	5,451,769	5,959,153	
Selling, general and administrative expenses	4,773,608	4,749,858	
Operating profit	678,161	1,209,294	
Non-operating income			
Interest and dividend income	26,095	18,651	
Royalty gain	8,104	4,548	
Rental income	27,353	31,705	
Subsidy income	-	9,672	
Other	17,188	30,712	
Total non-operating income	78,741	95,290	
Non-operating expenses			
Interest expenses	26,587	42,583	
Foreign exchange losses	37,541	46,077	
Commission expenses	8,000	8,000	
Other	8,551	1,713	
Total non-operating expenses	80,680	98,374	
Ordinary profit	676,222	1,206,211	
Extraordinary income			
Subsidy income	20,340	7,333	
Insurance claim income	9,013	19,808	
Surrender value of insurance policies	2,988	-	
Total extraordinary income	32,342	27,141	
Extraordinary losses			
Loss on sale and retirement of non-current assets	2,587	17,217	
Loss on disaster	4,500	7,297	
Guarantee loss	109,691	25,072	
Loss on cancellation of insurance policies	-	11,736	
Other	-	903	
Total extraordinary losses	116,779	62,227	
Profit before income taxes	591,785	1,171,125	
Income taxes - current	105,603	252,574	
Income taxes - deferred	68,861	(15,040)	
Total income taxes	174,464	237,533	
Profit	417,321	933,591	
Loss attributable to non-controlling interests	(192)	_	
Profit attributable to owners of parent	417,513	933,591	

## **Consolidated Statements of Comprehensive Income**

	Thousands of yen	
	For the FY ended	For the FY ended
	March 31, 2020	March 31, 2021
Profit	417,321	933,591
Other comprehensive income		
Valuation difference on available-for-sale securities	(58,133)	(1,081)
Foreign currency translation adjustment	(60,266)	98,922
Remeasurements of defined benefit plans, net of tax	(187,053)	439,552
Total other comprehensive income	(305,453)	537,394
Comprehensive income	111,868	1,470,985
Comprehensive income attributable to		
Comprehensive income attributable to owners of parent	113,276	1,470,985
Comprehensive income attributable to non-controlling interests	(1,408)	-



# Consolidated Statements of Cash Flows (1)

	Thousands of yen		
	For the FY ended March 31, 2020	For the FY ended	
		, 2020 March 31, 2021	
Cash flows from operating activities			
Profit before income taxes	591,785	1,171,125	
Depreciation	1,312,244	1,208,486	
Loss on disaster	4,500	7,297	
Guarantee loss	109,691	25,072	
Loss (gain) on sale and retirement of non-current assets	2,587	17,217	
Loss (gain) on cancellation of insurance policies	_	11,736	
Insurance claim income	(9,013)	(19,808)	
Surrender value of insurance policies	(2,988)	-	
Subsidy income	(20,340)	(7,333)	
Increase (decrease) in allowance for doubtful accounts	609	2,441	
Increase (decrease) in provision for bonuses	(31,732)	68,066	
Increase (decrease) in provision for share awards	19,980	(4,436)	
Decrease (increase) in retirement benefit asset	_	(321,973)	
Increase (decrease) in retirement benefit liability	241,996	(311,386)	
Interest and dividend income	(26,095)	(18,651)	
Interest expenses	26,587	42,583	
Foreign exchange losses (gains)	113,291	(66,251)	
Decrease (increase) in trade receivables	(26,006)	(535,975)	
Decrease (increase) in inventories	(412,928)	(450,782)	
Increase (decrease) in trade payables	127,239	279,271	
Increase (decrease) in long-term accounts payable - other	(11,596)	(115,865)	
Other, net	(389,043)	975,184	
Subtotal	1,620,769	1,956,019	
Interest and dividends received	26,095	18,651	
Interest paid	(25,273)	(45,219)	
Income taxes refund (paid)	(498,021)	(42,676)	
Proceeds from insurance income	9,013	19,808	
Proceeds from surrender value of Insurance	2,988	-	
Subsidies received	20,340	7,333	
Guarantee loss paid	(11,079)	(111,644)	
Payments associated with disaster loss		(11,797)	
Net cash provided by (used in) operating activities	1,144,832	1,790,473	



# Consolidated Statements of Cash Flows 2

	Thousands of yen		
	For the FY ended	For the FY ended	
	March 31, 2020	March 31, 2021	
Cash flows from investing activities			
Net decrease (increase) in time deposits	(11,004)	52,981	
Purchase of property, plant and equipment	(741,254)	(1,241,697)	
Purchase of intangible assets	(516,519)	(243,256)	
Purchase of investment securities	(253,033)	(54,598)	
Proceeds from cancellation of insurance funds	-	20,070	
Payments of leasehold and guarantee deposits	(2,417)	(11,446)	
Proceeds from refund of leasehold and guarantee deposits	2,029	3,632	
Other, net	(27,638)	(71,518)	
Net cash provided by (used in) investing activities	(1,549,839)	(1,545,832)	
Cash flows from financing activities			
Net increase (decrease) in short-term borrowings	998,895	-	
Proceeds from long-term borrowings	-	4,000,000	
Repayments of long-term borrowings	(1,021,033)	(1,355,036)	
Purchase of treasury shares	(598,999)	-	
Purchase of shares of subsidiaries not resulting in change			
in scope of consolidation	(44,744)	-	
Proceeds from disposal of treasury shares from exercise of			
subscription rights to shares	6,409	16,555	
Repayments of lease obligations	(52,164)	(65,776)	
Dividends paid	(447,659)	(394,324)	
Other, net	(17,377)	(26,396)	
Net cash provided by (used in) financing activities	(1,176,672)	2,175,021	
Effect of exchange rate change on cash and cash equivalents	(129,297)	83,020	
Net increase (decrease) in cash and cash equivalents	(1,710,976)	2,502,683	
Cash and cash equivalents at beginning of period	10,883,205	9,172,228	
Increase in cash and cash equivalents resulting from			
inclusion of subsidiaries in consolidation		6,797	
Cash and cash equivalents at end of period	9,172,228	11,681,709	





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